

Edition 1:2003 consolidated with amendments 1:2004 and 2:2006

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INTERNATIONAL SPECIAL COMMITTEE ON RADIO INTERFERENCE

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**Specification for radio disturbance and immunity  
measuring apparatus and methods –**

**Part 1-2:**

**Radio disturbance and immunity measuring  
apparatus – Ancillary equipment –  
Conducted disturbances**

*This **English-language** version is derived from the original **bilingual** publication by leaving out all French-language pages. Missing page numbers correspond to the French-language pages.*

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INTERNATIONAL ELECTROTECHNICAL COMMISSION  
INTERNATIONAL SPECIAL COMMITTEE ON RADIO INTERFERENCE

**SPECIFICATION FOR RADIO DISTURBANCE AND IMMUNITY  
MEASURING APPARATUS AND METHODS –**

**Part 1-2: Radio disturbance and immunity measuring apparatus –  
Ancillary equipment – Conducted disturbances**

FOREWORD

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International Standard CISPR 16-1-2 has been prepared by CISPR subcommittee A: Radio interference measurements and statistical methods.

This consolidated version of CISPR 16-1-2 consists of the first edition (2003), its amendment 1 (2004) [documents CIS/A/503/FDIS and CIS/A/521/RVD] and its amendment 2 (2006) [documents CIS/A/654/FDIS and CIS/A/670/RVD].

The technical content is therefore identical to the base edition and its amendments and has been prepared for user convenience.

It bears the edition number 1.2.

A vertical line in the margin shows where the base publication has been modified by amendments 1 and 2.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

The committee has decided that the contents of the base publication and its amendments will remain unchanged until the maintenance result date indicated on the IEC web site under "<http://webstore.iec.ch>" in the data related to the specific publication. At this date, the publication will be

- reconfirmed,
- withdrawn,
- replaced by a revised edition, or
- amended.

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## INTRODUCTION

CISPR 16-1, CISPR 16-2, CISPR 16-3 and CISPR 16-4 have been reorganised into 14 parts, to accommodate growth and easier maintenance. The new parts have also been renumbered. See the list given below.

Old CISPR 16 publications		New CISPR 16 publications	
CISPR 16-1	Radio disturbance and immunity measuring apparatus	→	CISPR 16-1-1 Measuring apparatus
		→	CISPR 16-1-2 Ancillary equipment – Conducted disturbances
		→	CISPR 16-1-3 Ancillary equipment – Disturbance power
		→	CISPR 16-1-4 Ancillary equipment – Radiated disturbances
		→	CISPR 16-1-5 Antenna calibration test sites for 30 MHz to 1 000 MHz
CISPR 16-2	Methods of measurement of disturbances and immunity	→	CISPR 16-2-1 Conducted disturbance measurements
		→	CISPR 16-2-2 Measurement of disturbance power
		→	CISPR 16-2-3 Radiated disturbance measurements
		→	CISPR 16-2-4 Immunity measurements
CISPR 16-3	Reports and recommendations of CISPR	→	CISPR 16-3 CISPR technical reports
		→	CISPR 16-4-1 Uncertainties in standardised EMC tests
		→	CISPR 16-4-2 Measurement instrumentation uncertainty
		→	CISPR 16-4-3 Statistical considerations in the determination of EMC compliance of mass-produced products
CISPR 16-4	Uncertainty in EMC measurements	→	CISPR 16-4-4 Statistics of complaints and a model for the calculation of limits

More specific information on the relation between the 'old' CISPR 16-1 and the present 'new' CISPR 16-1-2 is given in the table after this introduction (TABLE RECAPITULATING CROSS REFERENCES).

Measurement instrumentation specifications are given in five new parts of CISPR 16-1, while the methods of measurement are covered now in four new parts of CISPR 16-2. Various reports with further information and background on CISPR and radio disturbances in general are given in CISPR 16-3. CISPR 16-4 contains information related to uncertainties, statistics and limit modelling.

CISPR 16-1 consists of the following parts, under the general title *Specification for radio disturbance and immunity measuring apparatus and methods – Radio disturbance and immunity measuring apparatus*:

- Part 1-1: Measuring apparatus,
- Part 1-2: Ancillary equipment – Conducted disturbances,
- Part 1-3: Ancillary equipment – Disturbance power,
- Part 1-4: Ancillary equipment – Radiated disturbances,
- Part 1-5: Antenna calibration test sites for 30 MHz to 1 000 MHz.

## TABLE RECAPITULATING CROSS-REFERENCES

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### First edition of CISPR 16-1-2

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#### Clauses, subclauses

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#### Annexes

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## **SPECIFICATION FOR RADIO DISTURBANCE AND IMMUNITY MEASURING APPARATUS AND METHODS –**

### **Part 1-2: Radio disturbance and immunity measuring apparatus – Ancillary equipment – Conducted disturbances**

#### **1 Scope**

This part of CISPR 16 is designated a basic standard, which specifies the characteristics and performance of equipment for the measurement of radio disturbance voltages and currents in the frequency range 9 kHz to 1 GHz.

Specifications for ancillary apparatus are included for: artificial mains networks, current and voltage probes and coupling units for current injection on cables.

The requirements of this publication shall be complied with at all frequencies and for all levels of radio disturbance voltages and currents within the CISPR indicating range of the measuring equipment.

Methods of measurement are covered in Part 2, and further information on radio disturbance is given in Part 3 of CISPR 16.

#### **2 Normative references**

The following referenced documents are indispensable for the application of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

CISPR 14-1:2000, *Electromagnetic compatibility – Requirements for household appliances, electric tools and similar apparatus – Part 1: Emission*

CISPR 16-1-1:2003, *Specification for radio disturbance and immunity measuring apparatus and methods – Part 1-1: Radio disturbance and immunity measuring apparatus – Measuring apparatus*

CISPR 16-2-1:2003, *Specification for radio disturbance and immunity measuring apparatus and methods – Part 2-1: Methods of measurement of immunity and disturbance – Conducted disturbance measurements*

CISPR 16-3:2003, *Specification for radio disturbance and Immunity measuring apparatus and methods – Part 3: CISPR Technical reports*

CISPR 16-4-1:2003, *Specification for radio disturbance and immunity measuring apparatus and methods – Part 4-1: Uncertainties, statistics and limit modelling – Uncertainties in standardized EMC tests*

CISPR 16-4-2:2003, *Specification for radio disturbance and immunity measuring apparatus and methods – Part 4-2: Uncertainties, statistics and limit modelling – Measurement instrumentation uncertainties*

IEC 60050(161):1990, *International Electrotechnical Vocabulary (IEV) – Chapter 161: Electromagnetic compatibility*

*International Vocabulary of Basic and General Terms in Metrology*, International Organization for Standardization, Geneva, 2nd edition, 1993

### 3 Definitions

For the purpose of this part of CISPR 16, the following definitions apply. Also see IEC 60050(161).

#### 3.1

##### **symmetric voltage**

in a two-wire circuit, such as a single-phase mains supply, the symmetric voltage is the radio-frequency disturbance voltage appearing between the two wires. This is sometimes called the differential mode voltage. If  $V_a$  is the vector voltage between one of the mains terminals and earth and  $V_b$  is the vector voltage between the other mains terminal and earth, the symmetric voltage is the vector difference ( $V_a - V_b$ )

#### 3.2

##### **asymmetric voltage**

the asymmetric voltage is the radio-frequency disturbance voltage appearing between the electrical mid-point of the mains terminals and earth. It is sometimes called the common mode voltage and is half the vector sum of  $V_a$  and  $V_b$ , i.e.,  $(V_a + V_b)/2$

#### 3.3

##### **unsymmetric voltage**

the amplitude of the vector voltage,  $V_a$  or  $V_b$  defined in 3.1 and 3.2. This is the voltage measured by the use of an artificial mains V-network

#### 3.4

##### **artificial mains network**

###### **AMN**

provides a defined impedance to the EUT at radio frequencies, couples the disturbance voltage to the measuring receiver and decouples the test circuit from the supply mains. There are two basic types of AMN, the V-network (V-AMN) which couples the unsymmetrical voltages, and the delta-network which couples the symmetric and the asymmetric voltages separately. The terms line impedance stabilization network (LISN) and V-AMN are used interchangeably

#### 3.5

##### **asymmetric artificial network (AAN)**

network used to measure (or inject) asymmetric (common mode) voltages on unshielded symmetric signal (e.g. telecommunication) lines while rejecting the symmetric (differential mode) signal

NOTE The term "Y-network" is a synonym for AAN.

#### 3.6

##### **impedance stabilization network (ISN)**

generally an artificial network that provides a stabilized impedance to the EUT; often (e.g. in CISPR 22) used as a synonym for AAN

#### 3.7

##### **coupling/decoupling network (CDN)**

artificial network for the measurement or injection of signals on one circuit while preventing signals from being measured or injected on another circuit

### 3.8

#### **longitudinal conversion loss (LCL)**

in a one- or two-port network, a measure (a ratio expressed in dB) of the degree of unwanted transverse (symmetric mode) signal produced at the terminals of the network due to the presence of a longitudinal (asymmetric mode) signal on the connecting leads (definition from ITU-T Recommendation O.9<sup>1)</sup>)

## 4 Artificial mains networks

An artificial mains network is required to provide a defined impedance at radio frequencies at the terminals of the equipment under test, to isolate the test circuit from unwanted radio-frequency signals on the supply mains, and to couple the disturbance voltage to the measuring receiver.

There are two basic types of artificial mains networks, the V-network which couples the unsymmetric voltages, and the delta-network which couples the symmetric and the asymmetric voltages separately.

For each mains conductor, there are three terminals: the mains terminal for connection to the supply mains, the equipment terminal for connection to the equipment under test, and the disturbance output terminal for connection to the measuring equipment.

NOTE 1 Examples of circuits of artificial mains networks are given in annex A.

NOTE 2 This clause specifies impedance and isolation requirements for the AMN including the corresponding measurement methods. Some background and rationale on the AMN related uncertainties is given in 6.2.3 of CISPR 16-4-1 and in CISPR 16-4-2.

### 4.1 AMN impedance

The specification of the impedance of an artificial mains network includes magnitude and phase of the impedance measured at an EUT terminal with respect to reference earth, when the receiver port is terminated with 50  $\Omega$ .

The impedance at the EUT terminals of the artificial mains network defines the termination impedance presented to the equipment under test. For this reason, when a disturbance output terminal is not connected to the measuring receiver, it shall be terminated by 50  $\Omega$ . In order to assure accurate termination into 50  $\Omega$  of the receiver port, a 10-dB attenuator shall be used either inside or external to the network, the VSWR of which (seen from either side) shall be less than or equal to 1.2 to 1. The attenuation shall be included in the measurement of the voltage division factor (see 4.10).

The impedance between each conductor (except PE) of the EUT terminal and reference earth shall comply with 4.2, 4.3, 4.4, 4.5 or 4.6 as appropriate for any value of external impedance, including a short circuit connected between the corresponding mains terminal and reference earth. This requirement shall be met at all temperatures which the network may reach under normal conditions for continuous currents up to the specified maximum. The requirement shall also be met for peak currents up to the specified maximum.

1) ITU-T Recommendation O.9, *Measuring arrangements to assess the degree of unbalance about earth.*

Where the phase requirement cannot be met, the measured phase angles may be taken into account in the uncertainty budget according to CISPR 16-4-2. Annex I gives guidelines for the calculation of the uncertainty contribution of the phase if the tolerance is exceeded.

NOTE Since EUT connectors are not optimized for radio frequencies up to 30 MHz, the measurement of the network impedance must be carried out with special measurement adaptors to enable short connections. The NWA's OSM (open/short/matched) calibration is used to characterize the adaptors, taking the insertion loss and the conductor lengths of the adaptors into account.

#### 4.2 50 Ω/50 μH + 5 Ω artificial mains V-network (for use in the frequency range 9 kHz to 150 kHz)

The AMN shall have the impedance (magnitude and phase) versus frequency characteristic shown in Table 3 and Figure 1a in the relevant frequency range. Tolerances of ±20 % for the magnitude and of ±11,5° for the phase are permitted.

**Table 3 – Magnitudes and phase angles of the V-network (see Figure 1a)**

Frequency MHz	Impedance magnitude Ω	Phase angle Degree
0,009	5,22	26,55
0,015	6,22	38,41
0,020	7,25	44,97
0,025	8,38	49,39
0,030	9,56	52,33
0,040	11,99	55,43
0,050	14,41	56,40
0,060	16,77	56,23
0,070	19,04	55,40
0,080	21,19	54,19
0,090	23,22	52,77
0,100	25,11	51,22
0,150	32,72	43,35

NOTE If this AMN meets the combined impedance requirements of this subclause and 4.3., it can be used in the frequency range 150 kHz to 30 MHz as well.

**4.3 50 Ω/50 μH artificial mains V-network (for use in the frequency range 0,15 MHz to 30 MHz)**

The AMN shall have the impedance (magnitude and phase) versus frequency characteristic shown in Table 4 and Figure 1b in the relevant frequency range. Tolerances of ±20 % for the magnitude and of ±11,5° for the phase are permitted.

**Table 4 – Magnitudes and phase angles of the V-Network (see Figure 1b)**

Frequency MHz	Impedance magnitude Ω	Phase angle Degree
0,15	34,29	46,70
0,17	36,50	43,11
0,20	39,12	38,51
0,25	42,18	32,48
0,30	44,17	27,95
0,35	45,52	24,45
0,40	46,46	21,70
0,50	47,65	17,66
0,60	48,33	14,86
0,70	48,76	12,81
0,80	49,04	11,25
0,90	49,24	10,03
1,00	49,38	9,04
1,20	49,57	7,56
1,50	49,72	6,06
2,00	49,84	4,55
2,50	49,90	3,64
3,00	49,93	3,04
4,00	49,96	2,28
5,00	49,98	1,82
7,00	49,99	1,30
10,00	49,99	0,91
15,00	50,00	0,61
20,00	50,00	0,46
30,00	50,00	0,30

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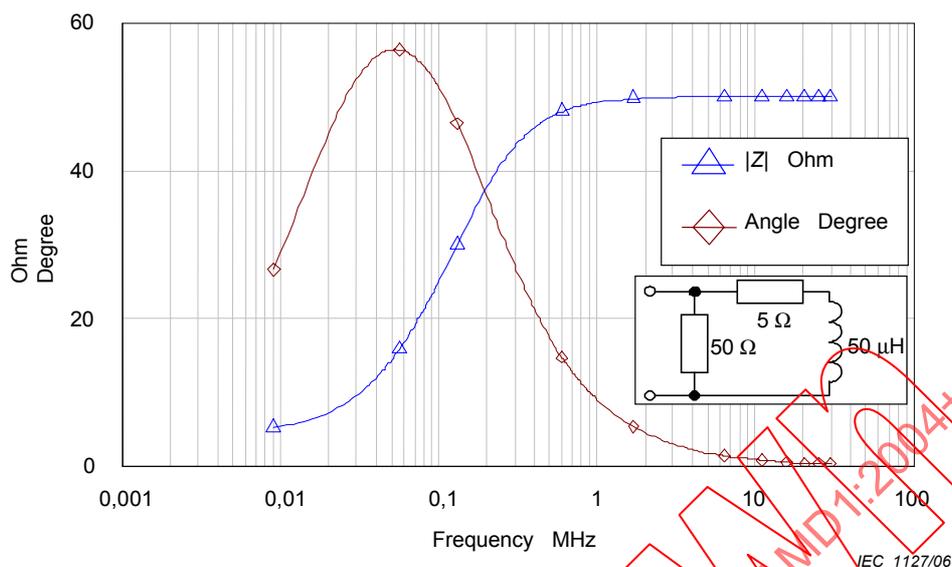
**4.4 50 Ω/5 μH + 1 Ω artificial mains V-network (for use in the frequency range 150 kHz to 100 MHz)**

The AMN shall have the impedance (magnitude and phase) versus frequency characteristic shown in Table 5 and Figure 2. Tolerances of ±20 % for the magnitude and of ±11,5° for the phase are permitted.

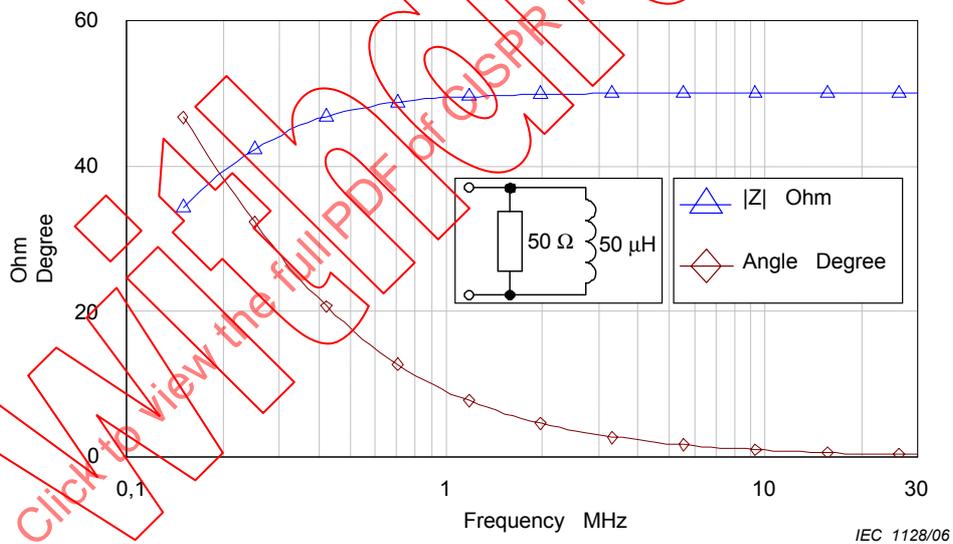
**Table 5 – Magnitudes and phase angles of the V-Network (see Figure 2)**

Frequency MHz	Impedance magnitude Ω	Phase angle Degree
0,15	4,70	72,74
0,20	6,19	73,93
0,30	9,14	73,47
0,40	12,00	71,61
0,50	14,75	69,24
0,70	19,82	64,07
1,00	26,24	56,54
1,50	33,94	46,05
2,00	38,83	38,15
2,50	41,94	32,27
3,00	43,98	27,81
4,00	46,33	21,63
5,00	47,56	17,62
7,00	48,71	12,80
10,00	49,35	9,04
15,00	49,71	6,06
20,00	49,84	4,55
30,00	49,93	3,04
50,00	49,97	1,82
100,00	49,99	0,91
108,00	49,99	0,84

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**Figure 1a – Impedance (magnitude and phase) of the V-network for band A**  
(see 4.2, the relevant frequency range is from 9 kHz to 150 kHz)



**Figure 1b – Impedance (magnitude and phase) of the V-network for band B**  
(see 4.3)

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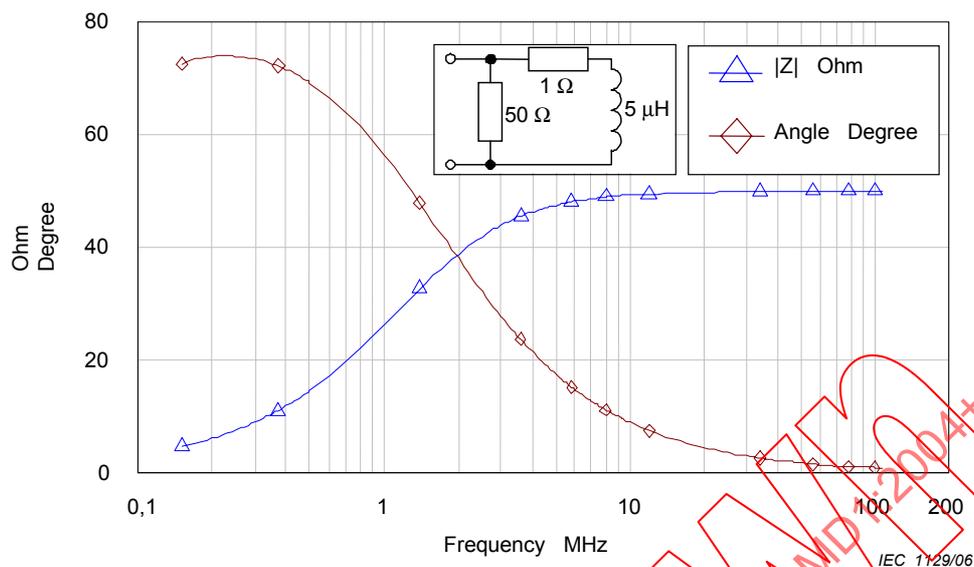


Figure 2 – Impedance (magnitude and phase) of the V-network for bands B and C (from 0,15 MHz to 108 MHz; see 4.4)

#### 4.5 150 $\Omega$ artificial mains V-network (for use in the frequency range 150 kHz to 30 MHz)

The network shall have an impedance of magnitude  $150 \pm 20 \Omega$  with a phase angle not exceeding  $20^\circ$ .

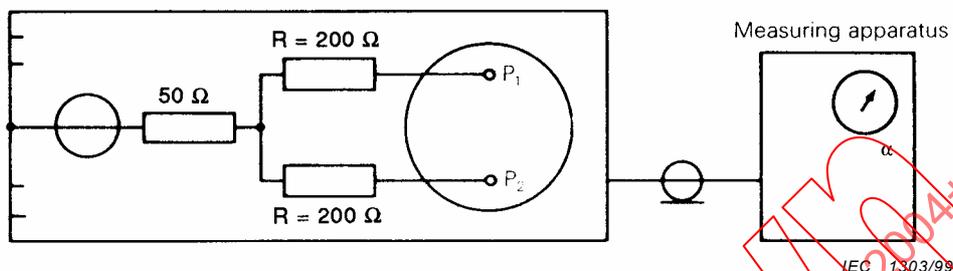
#### 4.6 150 $\Omega$ artificial mains delta-network (for use in the frequency range 150 kHz to 30 MHz)

The network shall have an impedance of magnitude  $150 \pm 20 \Omega$  with a phase angle not exceeding  $20^\circ$ , both between the equipment terminals and between the two equipment terminals joined together and reference earth.

For the measurement of the symmetric voltage, a screened and balanced transformer is required. To avoid appreciable modification of the impedance of the network, the input impedance of the transformer shall be not less than  $1\,000 \Omega$  at all frequencies concerned. The voltage measured by the measuring receiver depends on the network component values and the transformer ratio. The network shall be calibrated.

#### 4.6.1 Balance of the 150 Ω artificial mains delta-network

The balance of the system comprising the network and the measuring receiver connected thereto via the transformer shall be such that the measurement of symmetric voltage shall be substantially unaffected by the presence of an asymmetric voltage. The balance shall be measured using the circuit shown in figure 3.



R are the resistors of 200 Ω equal to each other within 1 %

P<sub>1</sub> P<sub>2</sub> are the terminals of network for connection of device

**Figure 3 – Method for checking the balance of the arrangement for the measurement of symmetrical voltages**

A voltage  $U_a$  is injected from a generator having an internal impedance of 50 Ω, between reference earth and the common point of two resistors each 200 Ω ± 1 %. The other end of these resistors is connected to the equipment terminals of the artificial mains network.

A voltage  $U_s$  is measured in the position for symmetric voltage measurement. The ratio  $U_a/U_s$  shall be greater than 20:1 (26 dB).

#### 4.7 Isolation

##### 4.7.1 Requirement

To ensure that at any test frequency, unwanted signals existing on the mains side and the unknown impedance of the supply mains do not affect the measurement, a minimum isolation (decoupling factor) between each mains terminal and the receiver port for a given termination of the relevant terminal of the EUT port shall be met. The requirement applies to the V-AMN itself excluding additional external cables and filters.

**Table 6 – Values of minimum isolation for V-Networks**

Clause	Type of V-network	Frequency range MHz	Minimum isolation dB
4.2	50 Ω/50μH + 5 Ω	0,009 – 0,05	0 – 40 <sup>*</sup> )
		0,05 – 30	40
4.3	50 Ω/50 μH	0,15 – 30	40
4.4	50 Ω/5 μH + 1 Ω	0,15 – 3	0 – 40 <sup>*</sup> )
		3 – 108	40

NOTE The values marked with an asterisk mean: minimum isolation rises linearly with the logarithm of frequency

NOTE Additional filtering external to the AMN may be required for the suppression of disturbance on the mains port (see CISPR 16-2-1 for practical requirements).

#### 4.7.2 Measurement procedure

The test setup is shown in Figure H.1. For the measurement, first a signal  $U_1$  is measured across a load impedance of  $50 \Omega$  with a source impedance of  $50 \Omega$ . Then this signal source shall be connected between the relevant mains terminal and reference ground, the relevant EUT terminals shall be terminated with  $50 \Omega$  and the output voltage  $U_2$  shall be measured at the receiver port (terminated with an impedance of  $50 \Omega$ ). The attenuation of the 10-dB attenuator described in 4.1 shall be added to the isolation requirement. The isolation requirement shall be met for all mains and EUT terminals. If the termination of the other mains terminals influences the measurement result, then the requirement shall be met with the other mains terminals open and shorted.

The following equation shall be met:

$$U_1 - U_2 \geq F_D + A$$

where

$U_1$  is the reference voltage at the mains terminals in dB( $\mu$ V);

$U_2$  is the output voltage at the receiver port in dB( $\mu$ V);

$F_D$  is the minimum isolation (decoupling factor) requirement in dB;

$A$  is the attenuation of the built-in attenuator in dB.

NOTE Since EUT connectors are not optimized for radio frequencies up to 30 MHz, the measurement of the network isolation must be carried out with special measurement adaptors to enable short connections. The measurement of  $U_1$  must be made with the adaptor connected to the source.

#### 4.8 Current carrying capacity and series voltage drop

The maximum continuous currents and the maximum peak current shall be specified. The voltage applied to the equipment under test when passing continuous currents up to the maximum shall be not less than 95 % of the mains voltage at the mains terminals of the artificial mains network.

#### 4.9 Modified reference earth connection

The measurement of some types of equipment may require the insertion of an impedance in the reference earth conductor in the artificial mains networks in 4.2 and 4.3 following the requirements of the related product publications. This is inserted at point X marked in the reference earth lead in figures 4 and 5, respectively. The impedance to be inserted is either a 1,6 mH inductor or an impedance conforming to the impedance requirement of 4.2 or 4.3, as appropriate for the frequency range.

NOTE For safety reasons, the  $5 \Omega$  resistor mentioned in 4.2 should be omitted.

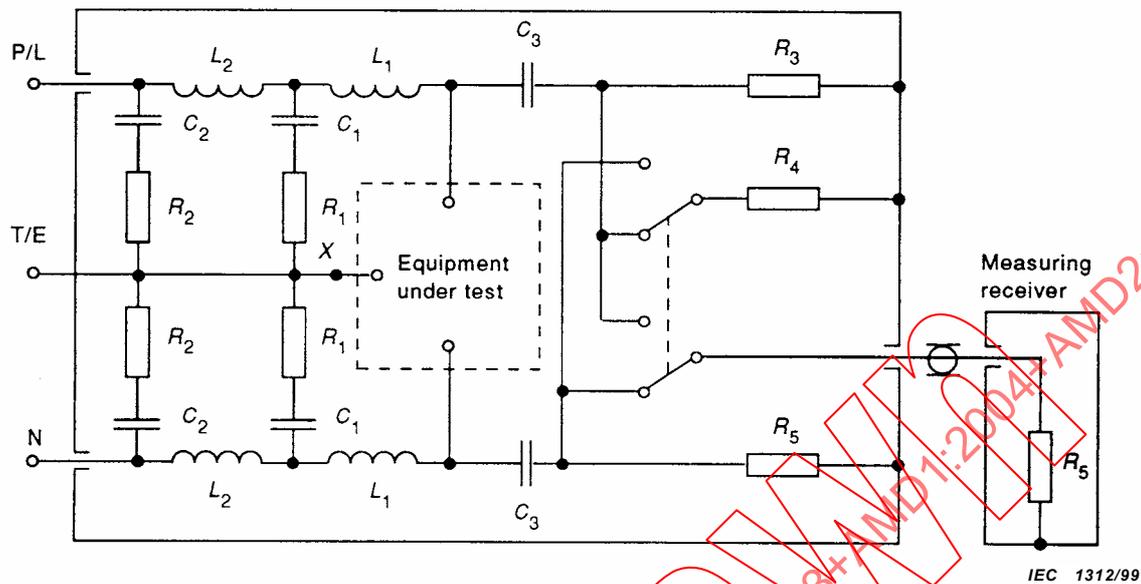


Figure 4 – Example of artificial mains  $50 \Omega/50 \mu\text{H} + 5 \Omega$  V-network  
(see 4.2 and clause A.2)

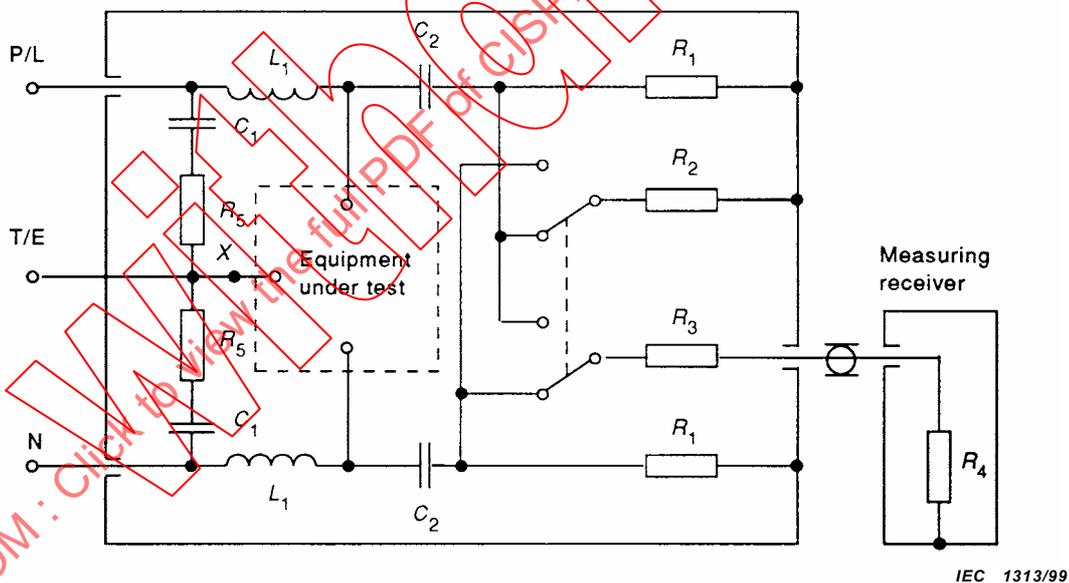


Figure 5 – Example of artificial mains V-networks,  $50 \Omega/50 \mu\text{H}$ ,  $50 \Omega/5 \mu\text{H} + 1 \Omega$  or  $150 \Omega$   
(see 4.3, 4.4, 4.5 and clauses A.3, A.4 and A.5, respectively)

#### 4.10 Calibration of the voltage division factor of artificial mains V-networks

The voltage division factor between the EUT port of the V-network and the RF output port shall be measured and taken into consideration during the measurement of the disturbance voltage. A procedure to measure the voltage division factor is contained in clause A.8.

## 5 Current and voltage probes

### 5.1 Current probes

The asymmetrical disturbance currents of cables can be measured, without making direct conductive contact with the source conductor and without modification of its circuit, by use of specially developed clamp-on current transformers. The utility of this method is self-evident; complex wiring systems, electronic circuits, etc., may be measured without interruption of the normal operation or configuration. The current probe is constructed so that it may be conveniently clamped around the conductor to be measured. The conductor represents a one-turn primary winding. The secondary winding is contained within the current probe.

Current probes can be constructed for measurements in the frequency range 30 Hz to 1 000 MHz, although the primary measurement range is 30 Hz to 100 MHz. Beyond 100 MHz the standing currents in conventional power systems require that the current probe location be optimized for detection of the maximum current.

Current probes are designed to provide a flat frequency response over a passband. At frequencies below this flat passband accurate measurements can still be made but with decreased sensitivity due to reduced transfer impedances. At frequencies above the flat passband measurements are not accurate due to resonances in the current probe.

With an additional shielding structure, a current probe may be used to measure either the asymmetrical (common mode) or symmetrical (differential mode) current. Clause B.5 of annex B contains some construction details.

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### 5.1.1 Construction

The current probe shall be constructed so as to enable the measurement of the current without disconnecting the lead under measurement.

Annex B contains some typical constructions of current probes.

### 5.1.2 Characteristics

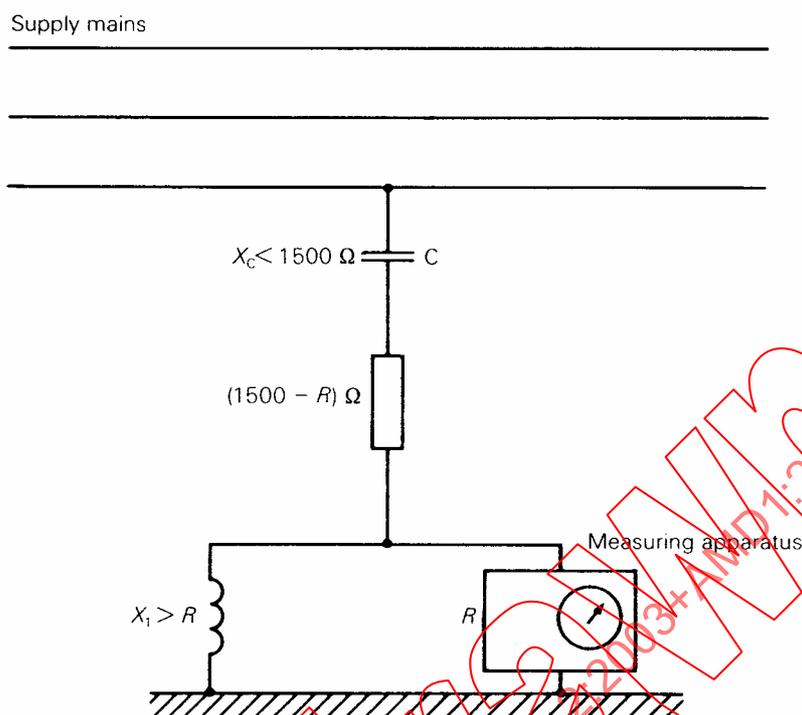
Insertion impedance	1 $\Omega$ impedance maximum
Transfer impedance*	0,1 to 5 $\Omega$ in the flat linear range; 0,001 to 0,1 $\Omega$ below the flat linear range (current probe terminated into 50 $\Omega$ )
Added shunt capacitance	Less than 25 pF between the current probe housing and measured conductor
Frequency response	Transfer impedance is calibrated over a specified frequency range; the range of individual probes is typically 100 kHz to 100 MHz, 100 MHz to 300 MHz, and 200 MHz to 1 000 MHz
Pulse response	Under consideration
Magnetic saturation	The maximum d.c. or a.c. mains current in the primary lead for a measurement error less than 1 dB shall be specified
Transfer impedance tolerance	Under consideration
Influence of external magnetic fields	40 dB reduction in indication when a current carrying conductor is removed from the current probe opening to a position adjacent to the probe
Influence of electric fields	Not susceptible to fields <10 V/m
Influence of orientation	Less than 1 dB up to 30 MHz and 2,5 dB from 30 MHz to 1 000 MHz, when used on a conductor of any size placed anywhere inside the aperture
Current probe opening	At least 15 mm

## 5.2 Voltage probe

### 5.2.1 High impedance voltage probe

Figure 6 shows a circuit which is used to make voltage measurements between a mains conductor and reference ground. The probe consists of a blocking capacitor C and a resistor such that the total resistance between line and earth is 1 500  $\Omega$ . The probe may also be used to make measurements on other lines and for certain applications its impedance may need to be increased to avoid excessive loading of high impedance circuits. An inductor may have to be connected across the input of the measuring apparatus, for safety reasons; its inductive reactive,  $X_C$ , to be much greater than R.

\* The reciprocal transfer admittance, (in dB(S)), may be used instead. When expressed in decibels, the admittance is added to the reading of the measuring receiver. For the calibration of the transfer impedance or admittance, it may be necessary to use a jig designed for the purpose. See annex B.



NOTE  $V = \frac{1\ 500}{R} U$

where

$V$  is the disturbing voltage

$U$  is the voltage at the input of the measuring apparatus

**Figure 6 – Circuit for RF voltage measurement on supply mains (see 5.2.1)**

The insertion loss of voltage probes shall be calibrated in a 50 Ω system over the frequency range of 9 kHz to 30 MHz. The effect on the accuracy of measurement of any device which may be used for protection should either be less than 1 dB or be allowed for in calibration. Care shall be taken to ensure that the level of disturbance is accurately measured in the presence of the ambient noise to make the measurement meaningful.

The loop formed by the lead connected to the probe, the mains conductor tested and reference ground should be minimized to reduce the effects of any strong magnetic fields.

### 5.2.2 Capacitive voltage probe

The asymmetrical disturbance voltages of cables can be measured without making direct conductive contact with the source conductor and without modification of its circuit by the use of a clamp-on capacitive coupling device. The usefulness of this method is self-evident; complex wiring systems, electronic circuits, etc. may be measured without interruption of the normal operation or configuration of the EUT or the need to cut the cable to insert a measuring device. The capacitive voltage probe is constructed so that it may be conveniently clamped around the conductor to be measured.

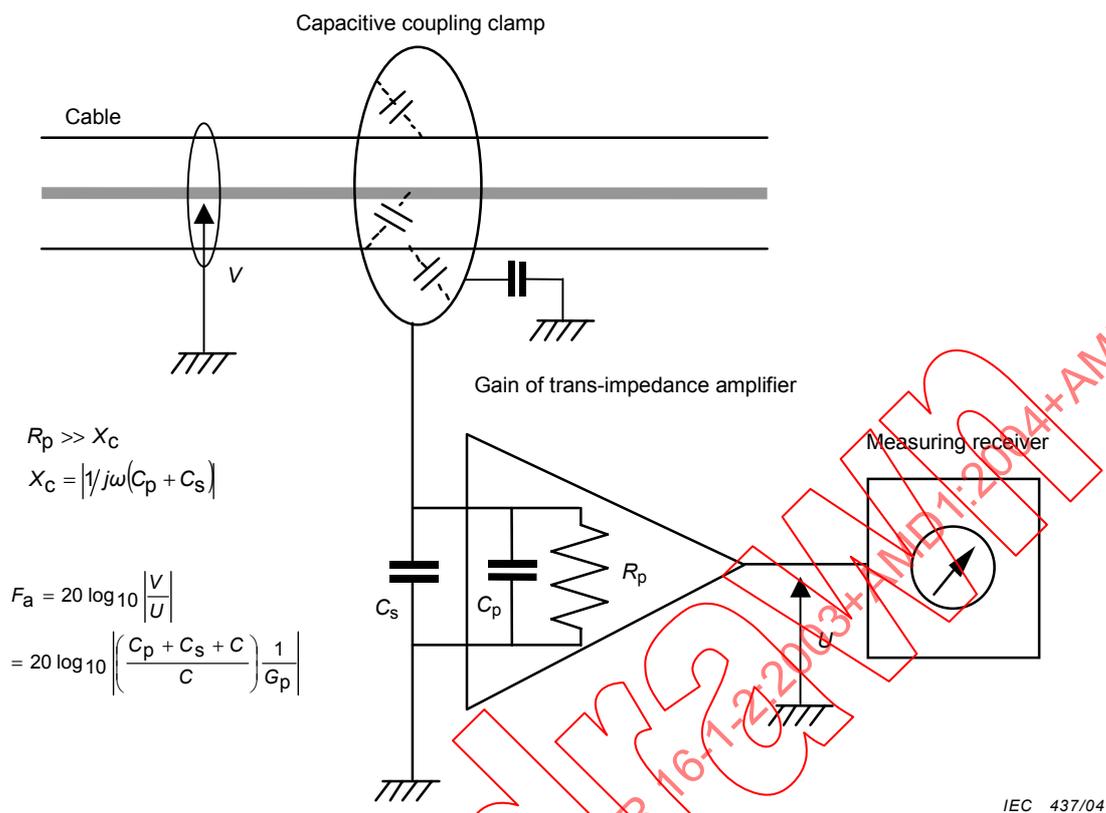
The capacitive voltage probe is used for measurements of conducted disturbances in the frequency range 150 kHz to 30 MHz with an almost flat frequency response in the frequency range of interest. The voltage division factor, which is defined as the ratio of the disturbance voltage on the cable to the input voltage at the measuring receiver, depends on the type of cable. This parameter should be calibrated over a specified frequency range for each cable type, using the method described in Annex G.

The capacitive voltage probe may need additional shielding to provide sufficient isolation from the asymmetrical (common mode) signal around the cable (see "Influence of electric field" in 5.2.2.2). Annex G contains an example of the construction and a method of measurement for the isolation.

This capacitive voltage probe can be used to measure the disturbances at telecommunication ports. The minimum measurable level is typically up to 44 dB( $\mu$ V).

#### 5.2.2.1 Construction

The capacitive voltage probe shall be constructed so as to enable the measurement of the voltage without disconnecting the cable under measurement. Figure 11 shows a circuit that is used to make voltage measurements between a cable and a reference ground. The probe consists of a capacitive coupling clamp which is connected to a trans-impedance amplifier. The input resistance  $R_p$  of this amplifier shall be large enough compared to the reactance  $X_c$  to obtain a flat frequency response.



**Key**

- $G_p$  Gain of trans-impedance amplifier
- $C$  Capacitance between the cable and the clamp
- $C_s$  Capacitance between probe and ground
- $C_p$  Capacitance of trans-impedance amplifier
- $R_p$  Resistance of trans-impedance amplifier
- $V$  Disturbance voltage
- $U$  Voltage at the input of the measuring receiver

**Figure 11 – Circuit used to make voltage measurement between a cable and a reference ground**

Annex G provides instructions for the typical construction and verification of the capacitive voltage probe.

### 5.2.2.2 Requirements

Added shunt capacitance:	Less than 10 pF between the grounding terminal of capacitive voltage probe and the cable under test.
Frequency response:	Voltage division factor, $F_a = 20 \log_{10} V/U $ in dB (see Figure 11), is calibrated over a specified frequency range.
Pulse response:	Maintain linearity for the pulse determined by the method in Annexes B and C of CISPR 16-1-1 for band B.
Influence of electric field: (influence caused by electrostatic coupling with other cables near the probe)	The voltage indication is reduced by more than 20 dB when a cable is removed from the capacitive voltage probe. The measurement method is described in Annex G.
Capacitive voltage probe aperture or opening: (aperture when the two coaxial electrodes open at the slot (see Figure G.1))	At least 30 mm

## 6 Coupling units for conducted current immunity measurement

The coupling units are designed to inject the disturbance current on to the leads under test and to isolate the other leads and any apparatus which is connected to the equipment under test from the effects of these currents. With a 150  $\Omega$  source impedance, there is a useful correlation between the RF disturbance field strength acting on a real installation and the e.m.f. that must be applied in the current injection method to produce the same degree of impairment, at least for frequencies up to 30 MHz. The immunity of an apparatus is expressed by this e.m.f. value. Annexes C and D give the principle of operation and examples of types of units and their construction.

### 6.1 Characteristics

The performance checks of the coupling units are done on the impedance in the frequency range 0,15 MHz to 30 MHz and on insertion loss in the frequency range 30 MHz to 150 MHz.

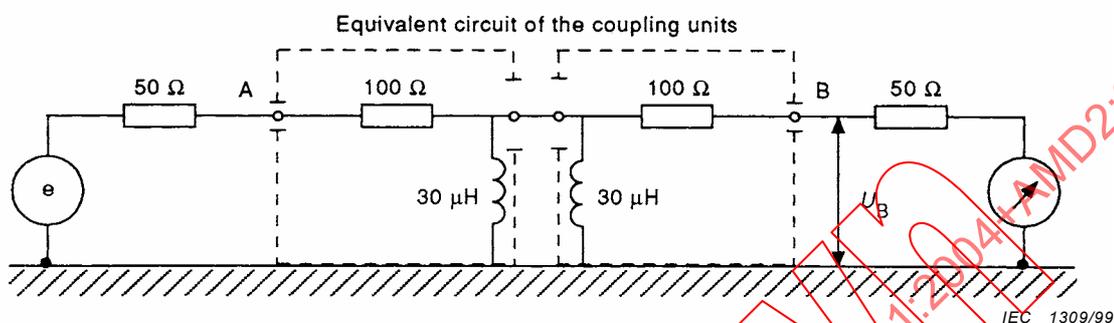
#### 6.1.1 Impedance

In the frequency range 0,15 MHz to 30 MHz, the total asymmetric impedance (RF choke coil in parallel with the 150  $\Omega$  resistive disturbance source impedance) measured between the point of injection of the disturbance signal to the equipment under test and the ground of the unit shall have a modulus of 150  $\Omega \pm 20 \Omega$  and a phase angle less than  $\pm 20^\circ$  (this impedance is the same as the CISPR 150  $\Omega$  artificial mains V-network, see 4.4).

For example, for coupling units type A and S, the point of injection is the shield of the output connector; for types M and L, the point of injection is the joint output terminals.

### 6.1.2 Insertion loss

In the frequency range 30 MHz to 150 MHz the insertion loss of two identical coupling units in tandem shall be within the range 9,6 dB to 12,6 dB, measured as shown in figure 7.



The insertion loss  $U_G/U_B$  of two identical coupling units measured according to this figure should be within 9,6 dB and 12,6 dB in the frequency range 30 MHz to 150 MHz.  $U_G$  is the reading of the receiver when the generator and receiver are directly connected together.

NOTE The two units shall be connected together with very short wires ( $\leq 1$  cm).

**Figure 7 – Measuring set-up to check the insertion loss of the coupling units in the frequency range 30 MHz to 150 MHz**

## 7 Coupling devices for measuring signal lines

The interference potential (and immunity) of signal lines may be assessed by measurement (or injection) of the conducted disturbance voltage or current. For this purpose coupling devices are needed to measure the disturbance component while rejecting the intentional signal on the line. The devices included are to measure the electromagnetic emission and immunity (common and differential mode, current and voltage). Typical devices for these kinds of measurements are current probes and asymmetric artificial networks (AANs or Y-networks).

NOTE 1 Requirements for AANs for conducted immunity tests on signal lines may be found in IEC 61000-4-6<sup>2)</sup> (AANs are special versions of “coupling and decoupling devices” [so called coupling/decoupling networks (CDNs)]). An AAN which meets the requirement for emission measurements may also meet the requirements for immunity testing.

NOTE 2 Signal lines include telecommunication lines and terminals of equipment intended to be connected to these lines.

NOTE 3 The terms “asymmetric voltage” and “common mode voltage” as well as “symmetric voltage” and “differential mode voltage” are synonyms, as defined in Clause 3.

NOTE 4 The term “asymmetric artificial network (AAN)” is used as synonym for “Y-network”, which is in contrast to V-networks and  $\Delta$ -networks. The T-network is a special version of the Y-network.

<sup>2)</sup> IEC 61000-4-6, *Electromagnetic compatibility (EMC) – Part 4-6: Testing and measurement techniques – Immunity to conducted disturbances, induced by radio-frequency fields*

When a current probe is used and the limit value is specified in volts, the voltage value must be divided by the impedance of the signal line or termination impedance as specified by the detailed measurement procedure, to obtain the limit value for the current. This impedance may be common mode as required by the detailed measurement procedure.

Subclause 7.1 states the specification for asymmetric (common mode) artificial networks (AANs). The differential mode to common mode rejection ( $V_{dm}/V_{cm}$ ) is crucial to the useability of the AAN. This parameter is related to the longitudinal conversion loss (LCL). An example of asymmetric artificial networks and the required test and calibration procedures are given in Annex E.

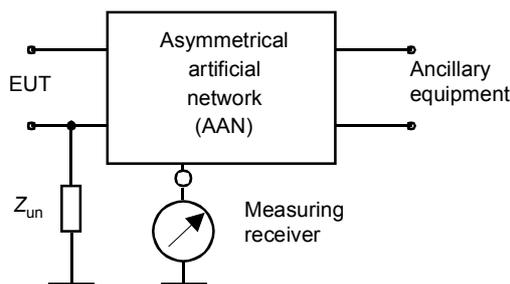
### 7.1 Requirements for asymmetric artificial networks (AANs or Y-networks)

Asymmetric artificial networks (AANs) are used to measure (or inject) asymmetric (common mode) voltages on unshielded symmetric signal (e.g. telecommunication) lines while rejecting the symmetric (differential mode) signal.

NOTE In CISPR 22 this type of network is called impedance stabilization network (ISN).

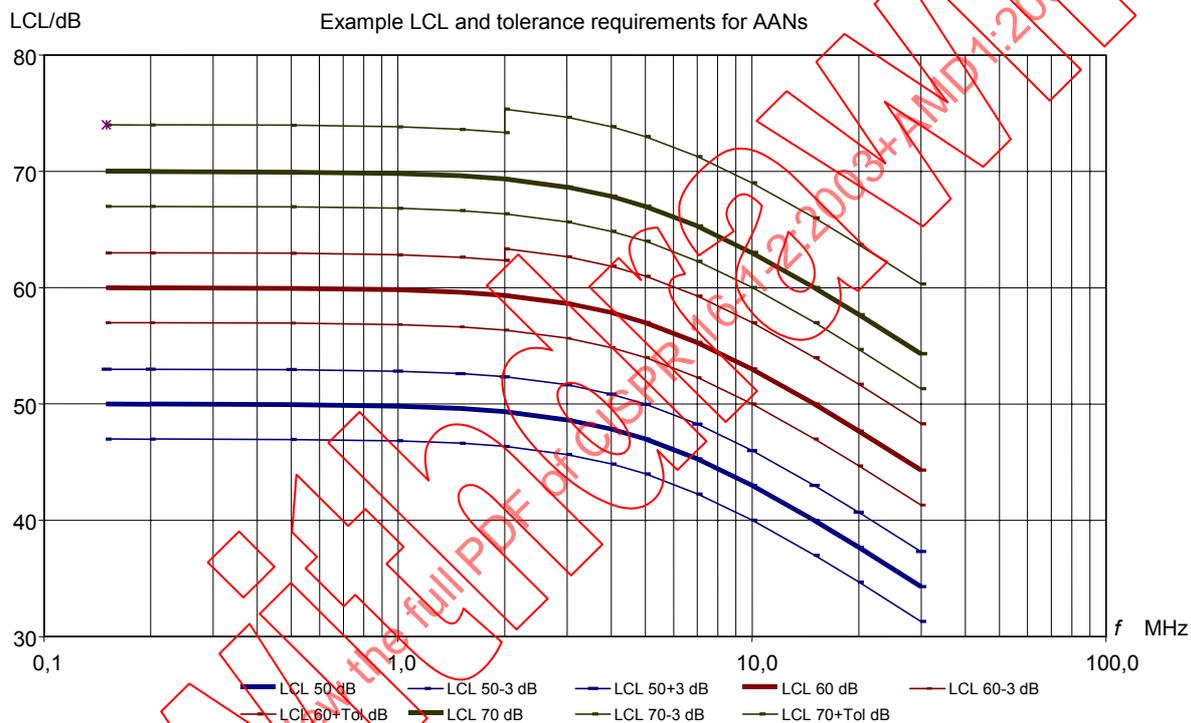
Figure 8a shows the general circuit diagram of an asymmetric artificial network.

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IEC 1127/03

Figure 8a – Principle circuit of the asymmetrical artificial network (AAN or Y-network) and its ports consisting of a basic highly symmetric network and an (optional) unbalance network  $Z_{un}$



IEC 1128/03

NOTE 1 The definition equation can e.g. be

$$LCL = LCL_{lf} - 10 \lg \left[ 1 + \left( \frac{f}{f_{corner}} \right)^2 \right] \pm Tol \text{ (in dB)}$$

where

$LCL_{lf}$  is the LCL at low frequencies, e.g. 50 dB,

$f$  is the frequency,

$f_{corner}$  is the corner frequency, e.g. 5 MHz, and

$Tol$  is the LCL tolerance, e.g. 3 dB

NOTE 2 The ideal values for “50 dB”, “60 dB” and “70 dB” are given as bold lines, whereas tolerance lines are drawn as thin lines.

Figure 8b – Graph showing example requirements for the longitudinal conversion loss (LCL) of the AAN (Y-network)

Figure 8 – Principle circuit and example LCL requirements of an AAN

The characteristics of the AAN for the measurement of asymmetric (common mode) disturbances shall be covering the frequency range of the asymmetric disturbance voltages as well as the frequency range used for the transmission of the intentional signal. These characteristics are given in Table 1.

**Table 1 – Characteristics of the asymmetric artificial network for the measurement of asymmetric disturbance voltage**

a.	<b>Termination impedance</b> of basic network for asymmetric disturbance voltage <sup>a</sup> <ul style="list-style-type: none"> <li>• magnitude</li> <li>• phase</li> </ul>	150 Ω ± 20 Ω 0° ± 20°
b.	<b>Longitudinal conversion loss (LCL) at the EUT port</b> of the network <sup>b</sup>	(9 kHz to 150 kHz: to be defined) 0,15 MHz to 30 MHz: defined by the relevant product standard, e.g. as shown in Figure 8b <sup>c</sup>
c.	<b>Decoupling attenuation</b> for asymmetric signals between AE port and EUT port	(9 kHz to 150 kHz: to be defined) 0,15 MHz to 1,5 MHz: >35 dB to 55 dB increasing linearly with the log. of frequency ≥1,5 MHz: > 55 dB
d.	<b>Insertion loss of the symmetric circuit</b> between EUT and AE ports	<3 dB <sup>d</sup>
e.	<b>Voltage division factor of the asymmetric circuit</b> between EUT and measuring receiver ports, to be added to the reading of the measuring receiver	Typically 9,5 dB <sup>e</sup>
f.	<b>Symmetric load impedance</b> of the network	t.b.d. <sup>f</sup>
g.	<b>Transmission bandwidth</b> for the intentional signal (analog or digital)	t.b.d. <sup>g</sup>
h.	<b>Frequency range</b> <sup>h</sup> <ul style="list-style-type: none"> <li>(1) Emission</li> <li>(2) Immunity</li> </ul>	(0,009) 0,15 MHz to 30 MHz See e.g. IEC 61000-4-6
<p><sup>a</sup> The asymmetric impedance of the AAN will normally be influenced by the addition of an unbalanced network according to Figure 8a. This standard specifies the impedance tolerance for the basic network. If the influence of the unbalanced network on impedance and phase is negligible, the given tolerance may apply including the unbalanced network. If this is not the case, e.g. if the unbalanced network changes the impedance by more than 10 Ω or the phase by more than 10°, the product standard shall take this into account when specifying tolerances for impedance and phase, since a certain tolerance should be left to the AAN manufacturer.</p> <p><sup>b</sup> Different concepts for determination of conformance of equipment are in use: use an LCL of the AAN higher than the available LCL values of signal lines or use the LCL to simulate available telecommunication line categories.</p> <p><sup>c</sup> The values of LCL in Figure 8b have been taken – with modified tolerances – from a draft of the amendment to CISPR 22:1997. Other values may be defined by future product standards. Therefore the LCL requirements given in this publication are examples only. Generally, 3 factors have to be considered for LCL tolerances: the residual LCL of the basic AAN, the deviation of the unsymmetry network <math>Z_{un}</math> from nominal and the uncertainty of LCL measurement. The tolerances given in a product standard should take into account that acceptable tolerances should increase with the required LCL and with frequency. Figure 8b shows an example of reasonable tolerances.</p> <p><sup>d</sup> The actual requirements will depend on the specifications of the transmission system. Some transmission systems allow insertion losses of up to 6 dB. The insertion loss caused by an AAN is dependent on source and load impedances of the whole symmetric circuit. For lower/higher impedances the insertion loss will be lower/higher, and should be given by the manufacturer, e.g. for 100 Ω. In addition, it will be useful if manufacturers specify the phase characteristics of the AAN in its symmetric circuit.</p> <p><sup>e</sup> The AAN shall be calibrated by measuring the voltage division factor in a test set-up according to Figure E.6</p> <p><sup>f</sup> t.b.d. = to be defined, i.e. depending on the system specifications, e.g. 100 Ω or 600 Ω</p> <p><sup>g</sup> t.b.d. = to be defined, i.e. depending on the system specifications for the symmetric insertion loss, e.g. up to 2 MHz or up to 100 MHz</p> <p><sup>h</sup> More than one network may be used to cover the complete frequency range.</p>		

## 7.2 Requirements for artificial networks for coaxial and other screened cables

Artificial networks for coaxial and other screened cables are used to measure (or inject) unsymmetric (common mode) voltages on the shield of (e.g. telecommunication or r.f.) cables while passing the communication or r.f. signal through. The required characteristics are given in Table 2.

NOTE 1 In CISPR 22 this type of network is called coaxial or screened cable impedance stabilization network (ISN).

**Table 2 – Characteristics of artificial networks for coaxial and other screened cables**

a.	<b>Termination impedance</b> of basic network for unsymmetric disturbance voltage: <sup>a</sup> <ul style="list-style-type: none"> <li>• magnitude</li> <li>• phase</li> </ul>	150 Ω ± 20 Ω 0° ± 20°
b.	<b>Decoupling attenuation</b> <sup>b</sup> for unsymmetric signals between AE port and EUT port.	(9 kHz to 150 kHz: to be defined) 0,15 MHz to 30 MHz: >40 dB
c.	<b>Insertion loss and transmission bandwidth</b> for the intentional (communication or r.f.) signal between EUT and AE ports, including <b>characteristic impedance(s)</b>	Defined by system requirements <sup>c</sup>
d.	<b>Voltage division factor of the unsymmetric circuit</b> between EUT and measuring receiver ports, to be added to the reading of the measuring receiver.	Typically 9,5 dB <sup>d</sup>
e.	<b>Frequency range</b> (1) Emission (2) Immunity	(0,009) 0,15MHz to 30 MHz See e.g. IEC 61000-4-6
<p><sup>a</sup> The asymmetric impedance of the AN will be determined by the 150-Ω resistor in parallel with the choke and the capacitance of the bulkhead connector to ground.</p> <p><sup>b</sup> Since the coaxial cable shield at the AE port is directly connected to the AN metal case, the decoupling attenuation will not be a problem of the AN itself. The emission (or immunity) test set-up shall be so that the minimum decoupling attenuation can be guaranteed.</p> <p><sup>c</sup> Insertion loss and transmission bandwidth for the intentional (communication or r.f.) signal between EUT and AE ports as well as the characteristic impedances between shield and inner conductor(s) are not the purpose of this standard. They should be defined according to system requirements.</p> <p><sup>d</sup> The AN shall be calibrated by measuring the voltage division factor in a test set-up according to Figure F.2.</p>		

## 8 The artificial hand and series RC element

### 8.1 Introduction

In some product specifications the artificial hand is required for EUTs which do not have an earth ground connected to the metallic parts of the EUT and which in normal use are hand-held. Housings of plastic with a conductive coating may also require the use of the artificial hand. The artificial hand is used in conducted emission tests in the frequency range of 150 Hz to 30 MHz (the most critical frequencies are 5 MHz–30 MHz) to simulate the influence of the operator's hands on the measurements. The types of equipment to be evaluated with the artificial hand are: electric tools, household equipment, such as hand-held mixers, telephone handsets, joysticks, keyboards, etc.

## 8.2 Construction of the artificial hand and RC element

The artificial hand consists of a (strip of) metal foil of specified dimensions, which is placed on or wrapped around that part of the equipment normally touched by the user's hand, in a specified way.

The metal foil is connected in a specified way to the reference point of the disturbance measuring system via an RC element consisting of a capacitor  $C = 220 \text{ pF} \pm 20 \%$  in series with a resistor  $R = 510 \text{ } \Omega \pm 10 \%$  (see figure 9a).

The strips of metal foil used to simulate the influence of a user's hand around an equipment handle or an equipment body are typically 60 mm wide. In the case of a keyboard a metal foil, or more practically a metal plate of maximum dimensions 100 mm  $\times$  300 mm, may be placed on top of the keys. Examples are given in figures 9 and 10.

The lead length between the RC element and the metal foil shall be 1 m long. If the test set-up requires a longer lead length, the total inductance of the lead shall be less than 1,4  $\mu\text{H}$  if the frequency of measurement is near 30 MHz.

When considering the total of the interconnecting wires as a single wire in free space, the inductance  $L$  of the wire shall be less than 1,4  $\mu\text{H}$  if the upper limit of the frequency range in the conducted emission test is 30 MHz. For a given single-wire length this requirement allows the calculation of the minimum diameter  $d$  (in metres) of the wires to be used from:

$$L = \frac{\mu l}{2\pi} \left[ \ln \left( \frac{4l}{d} \right) - 1 \right] \quad (\text{H})$$

where

$$\mu = 4\pi \times 10^{-7} \text{ H/m};$$

$l$  is the length of the wire, in metres

$d$  is the diameter of the wire, in metres

NOTE When complying with the inductance requirement of 1.4  $\mu\text{H}$ , the impedance of the RC network sufficiently dominates at 30 MHz.

## 8.3 The use of the artificial hand

The maximum length of wire between the RC element and the reference ground is generally met when the wire length does not exceed 1 m. The RC element may, for example, be placed either as close as possible to the metal foil or as close as possible to the reference point. The correct choice largely depends on the (generally unknown) internal common mode impedance of the disturbance source in the presence of the metal foil and the characteristic impedance of the transmission line formed by the connecting wire and its environment. If the frequency range of the emission measurements is limited to 30 MHz, the position of the RC element is not critical, and a practical position (also from the reproducibility point of view) of the RC element is inside the artificial mains network or the line impedance simulation network.

When the conducted emission to the mains is measured, the reference point is the reference ground in the artificial mains network (AMN). When this emission is measured on a signal or control line, the reference point is the reference ground of the line impedance simulation network (LISN). The general principle to be followed in the application of the artificial hand is that terminal M of the RC element shall be connected to any exposed non-rotating metalwork and to metal foil wrapped around all handles, both fixed and detachable, supplied with the appliance. Metalwork which is covered with paint or lacquer is considered an exposed metalwork and shall be directly connected to the RC element.

The following items specify the detailed application of the artificial hand:

- a) When the housing of the appliance is entirely of metal and is earth-grounded, the artificial hand is not required.
- b) When the case of the appliance is of insulating material, metal foil shall be wrapped around the handle B (figure 9c) and also around the second handle D, if present. Metal foil 60 mm wide shall also be wrapped around the body C (see figure 9c) at the point where the iron core of the motor stator is located, or around the gearbox if this gives a higher interference level. All these pieces of metal foil, and the metal ring or bushing A, if present, shall be connected together and to the terminal M of the RC element.
- c) When the case of the appliance is partly metal and partly insulating material, and has insulating handles, metal foil shall be wrapped around the handles B and D (figure 9c). If the case is non-metallic at the location of the motor, a metal foil 60 mm wide shall be wrapped around the body C at the point where the iron core of the motor stator is located, or alternatively around the gearbox, if this is of insulating loading material and a higher interference level is obtained. The metal part of the body, the point A, the metal foil around the handles B and D and the metal foil on the body C shall be connected together and to the terminal M of the RC element.
- d) When a class II appliance (without ground wire) has two handles of insulating material A and B and a case of metal C, for example an electric saw (figure 9c), metal foil shall be wrapped around the handles A and B. The metal foil at A and B and the metal body C shall be connected together and to terminal M of the RC element.
- e) Figure 10 gives examples for a telephone handset and a keyboard. For the handset, the 60 mm wide foil is wrapped around the handle with some overlap of the foil. In the case of a keyboard the foil or the PCB should fully cover the keys as far as possible. Using a PCB, the metal side has to be placed on the keyboard. It does not, however, need to exceed the dimensions of 300 mm × 100 mm.

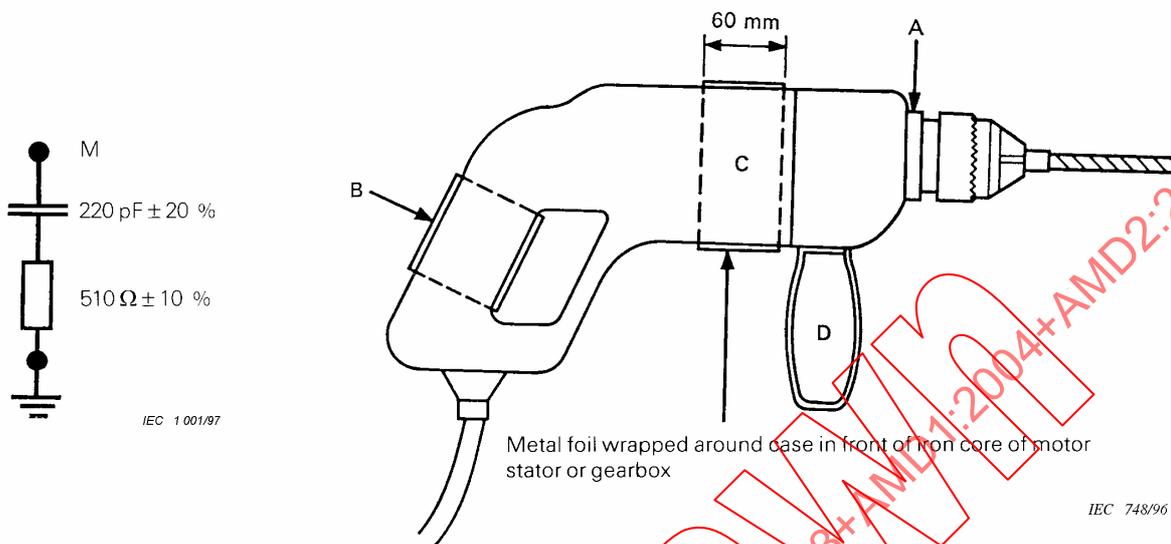


Figure 9a – RC element

Figure 9b – Portable electric drill

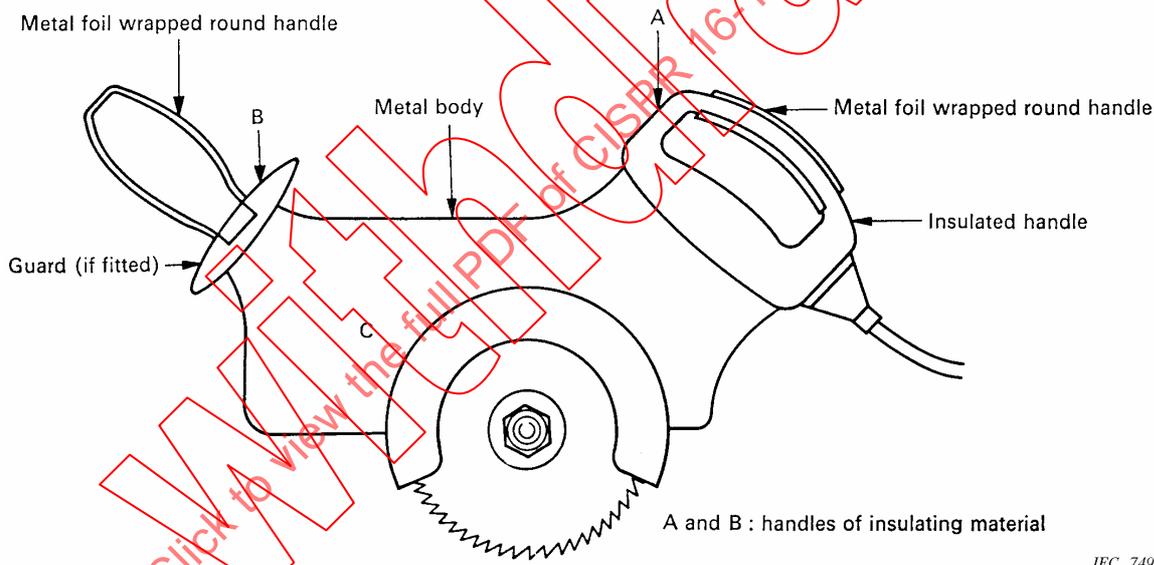


Figure 9c – Portable electric saw

Figure 9 – Application of the artificial hand

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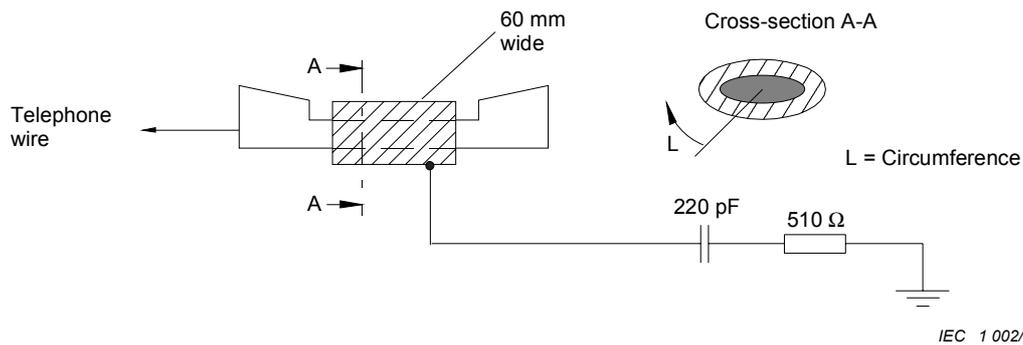


Figure 10a – Application of artificial hand to telephone handset

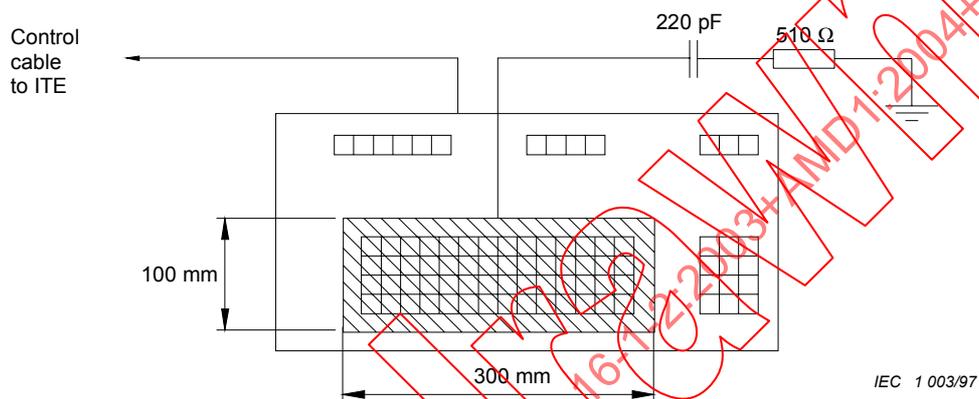


Figure 10b – Application of artificial hand to typical keyboard

The artificial hand incorporates a metal foil, with the following dimensions:

a) 60 mm wide and greater than $L$ in length	for parts of the equipment that are hand-held during operation, or at a maximum of 4
b) 300 mm × 100 mm	for keyboards, whereby the metal foil is to be sized in order to cover the total number of keys, or to partially cover the keyboard, when the keyboard dimensions are greater than the maximum foil size.

Figure 10 – Examples of application of artificial hand to ITE

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## Annex A (normative)

### Artificial mains networks (clause 4)

This annex sets forth information and data concerning artificial mains networks used in the measurement of radio-frequency (RF) voltages over the frequency range 9 kHz to 100 MHz and having current carrying capabilities of up to 500 A. Included are V-networks for voltage measurements between each conductor of the supply mains and reference earth, and delta-networks for voltage measurements between conductors of the supply mains (symmetrical) and between the mid-point of the conductors of the supply mains and reference earth (asymmetrical).

#### A.1 General

An artificial mains network circuit has to provide firstly the specified impedance over the working frequency range. It has to provide sufficient isolation to spurious signals in the mains supply (the spurious signals generally should be at least 10 dB below the measurement level at the measuring receiver). Also it has to prevent the mains voltage from being applied to the measuring receiver. It should have these provisions for each conductor of the mains (two-wire in single-phase and four-wire in three-phase), a switch to connect the measuring receiver to the mains conductor under measurement and to provide the correct termination to the other mains conductors. The circuits given in the following have these facilities. They are given for the case of two-wire single-phase mains. The extension to four-wire three-phase use is simply done.

#### A.2 An example of the 50 Ω/50 μH + 5 Ω artificial mains V-network

Figure 4 shows a suitable circuit with the component values listed in table A.1. L1, C1, R1, R4 and R5 define the impedance, L2, C2 and R2 provide the isolation to spurious mains signals and mains impedance variations, and C3 decouples the measuring receiver from mains voltage. It may be constructed for use with currents up to 100 A.

**Table A.1 – Component values of 50 Ω/50 μH + 5 Ω network**

Component	Value
R1	5 Ω
R2	10 Ω
R3	1000 Ω
R4	50 Ω
R5	50 Ω (input impedance the measuring receiver)
C1	8 μF
C2	4 μF
C3	0,25 μF
L1	50 μH
L2	250 μH

At the lowest frequencies of the range 9 kHz to 150 kHz, the 0,25  $\mu\text{F}$  capacitance of C3 does not have a negligible impedance. Unless otherwise specified, it will be necessary to make a correction for this impedance.

Since C1 and C2 have high capacitances, for safety reasons the network case should either be solidly bonded to reference earth or a mains isolating transformer should be used.

The inductance L2 should have a Q-factor not less than 10 over the 9 kHz to 150 kHz frequency range. In practice, it is advantageous to use inductors coupled in series opposition in the live and neutral lines (common-core choke).

Clause A.7 describes a suitable construction for the inductor L1. For equipment requiring currents greater than 25 A, difficulties may be encountered in the construction of L2. In this case the isolating section L2, C2 and R2 may be omitted. The effects will be that the impedance of the network at frequencies below 150 kHz may be outside the tolerance specified in 4.2, and the isolation of mains noise may not be sufficient.

This circuit may also satisfy the requirements of the 50  $\Omega$  /50  $\mu\text{H}$  artificial mains V-network specified in 4.3.

### A.3 An example of the 50 $\Omega$ /50 $\mu\text{H}$ artificial mains V-network

Figure 5 shows the circuit with the components values as listed in the table A.2. L1, C1, R2, R3 and R4 define the impedance. Unlike the previous example, there is no isolating section since the circuit is able to meet the impedance specification. However, in cases of high ambient mains noise a filter is required to reduce the spurious signal level. This network may be constructed for use with currents up to 100 A.

**Table A.2 – Component values of 50  $\Omega$ /50  $\mu\text{H}$  network**

Component	Value
R1	1000 $\Omega$
R2	50 $\Omega$
R3	0 $\Omega$
R4	50 $\Omega$ (input impedance of the measuring receiver)
R5	0 $\Omega$
C1	1 $\mu\text{F}$
C2	0,1 $\mu\text{F}$
L1	50 $\mu\text{H}$

Since C1 has a high capacitance, for safety reasons the network case shall either be solidly bonded to reference earth or a mains isolating transformer shall be used.

Clause A.7 describes a suitable construction for the inductor L1.

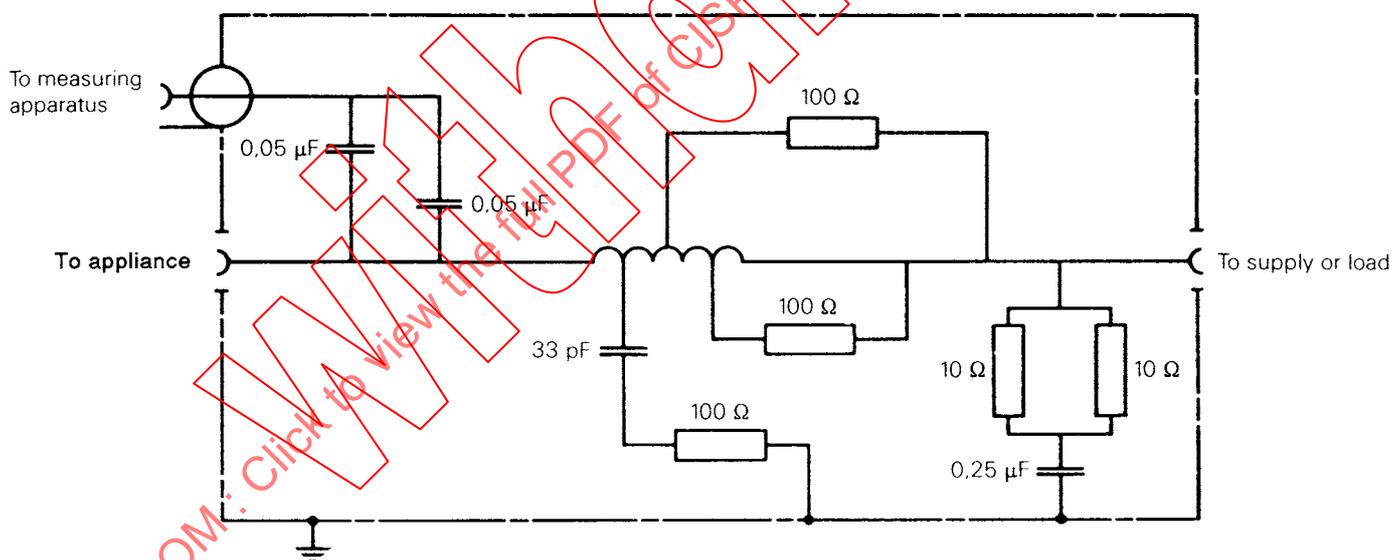
#### A.4 Examples of the 50 Ω/5 μH + 1 Ω artificial mains V-network

The circuit of figure 5 with the component values given in the table A.3 is suitable for frequencies 150 kHz to 30 MHz, and currents up to 400 A.

**Table A.3 – Component values of 50 Ω/5 μH + 1 Ω network**

Component	Value
R1	1 000 Ω
R2	50 Ω
R3	0 Ω
R4	50 Ω (input impedance of the measuring receiver)
R5	1 Ω
C1	2 μF (minimum)
C2	0,1 μF
L1	5 μH

An alternative circuit with component values is shown in figure A.1. It is suitable for the frequency range 150 kHz to 100 MHz, and for currents up to 500 A.



Coil details:

5 μH, 18 turns, Ø 6 mm wound on 50 mm diameter former. Tapping points at 3, 5, 9 and 13,5 turns.

**Figure A.1 – Example of an alternative 50 Ω/5 μH + 1 Ω artificial mains network for devices used with low impedance power sources**

### A.5 An example of the 150 Ω artificial mains V-network

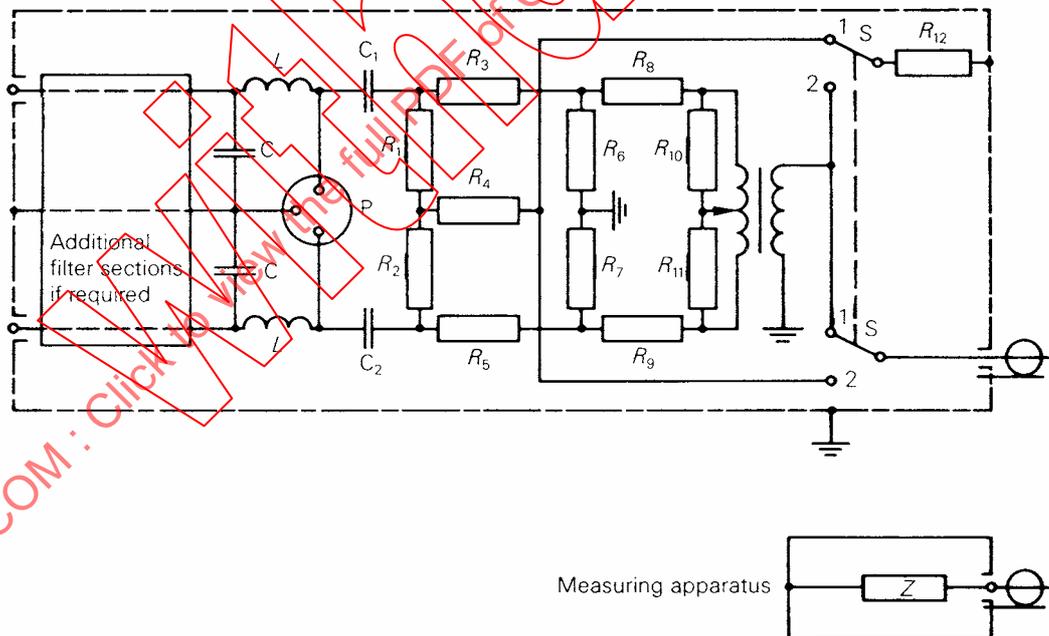
Figure 5 shows a suitable circuit. The component values are given in table A.4.

**Table A.4 – Component values of the 150 Ω V-network**

Component	Value
R1	1 000 Ω
R2	150 Ω
R3	100 Ω
R4	50 Ω (input impedance of the measuring receiver)
R5	0 Ω
C1	1 μF
C2	0,1 μF
L1	suitable value to achieve the specified impedance

### A.6 Example of the 150 Ω artificial mains delta-network

Figure A.2 shows a suitable circuit. The component values are given in table A.5.



- P is the connection for apparatus under test
- 1 for the symmetrical component
- 2 for the asymmetrical component

**Figure A.2 – Example of an artificial mains network (delta) for measuring apparatus with unbalanced input**

**Table A.5 – Component values of the 150 Ω delta-network**

Component	Value
R1, R2	118,7 (120) Ω
R3, R5	152,9 (150) Ω
R4	390,7 (390) Ω
R6, R7	275,7 (270) Ω
R8, R9	22,8 (22) Ω
R10, R11	107,8 (110) Ω
R12	50 Ω
C1, C2	0,1 μF
L, C	suitable value to achieve the specified impedance

NOTE 1 The turns ratio of the balanced to unbalanced transformer is assumed to be 1:2,5 with center tap.

NOTE 2 Resistance values shown in brackets are the nearest preferred values (±5 % tolerance).

Calculations give the following network performance. Values in brackets are based on the resistance values in brackets.

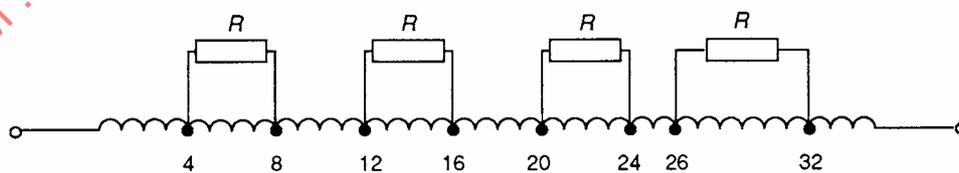
Attenuation:                    Symmetrical    20 (20) dB  
    Asymmetrical    20 (19,9) dB

Network impedance:        Symmetrical    150 (150) Ω  
    Asymmetrical    150 (148) Ω

## A.7 An example of a design for an artificial mains network with a 50 μH inductor

### A.7.1 The inductor

The solenoidal winding of the inductor shown in figure A.3 consists of 35 turns of a single layer of 6 mm diameter copper wire with an 8 mm pitch wound on a coil former of an insulating material. Its inductance is greater than 50 μH outside the metal case and 50 μH inside the metal case.



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Resistors R (430 Ω ± 10 %) are connected to taps at turns 4 and 8, 12 and 16, 20 and 24, 26 and 32. Inductance is 50 μH ± 10 %.

**Figure A.3 – Schematic of 50 μH inductor**

The diameter of the inductor is 130 mm. In order to improve the electrodynamic stability of the winding, a 3 mm deep spiral groove is made in the coil former, and the wire is laid in this groove.

The higher frequency characteristics of the inductor are improved by sectionalizing the winding. Alternate sections, each of 4 turns, are each shunted by a 430  $\Omega$  resistor. These act to suppress internal resonances in the inductor, which otherwise would cause the input impedance to deviate from the specified value at certain frequencies.

### A.7.2 The case of the inductor

The inductor and the other components of the network are mounted on a metal frame which is then closed by metal lids. The bottom and side lids are perforated in order to improve the heat dissipation. The dimensions of the case are 360  $\times$  300  $\times$  180 mm. Figure A.4 shows a general view.

NOTE It is recommended that the load-end terminals of the network be located as near as possible to a corner of that end of the case, so that two or more networks may be assembled with short leads from these terminals to the socket to be used for attachment of the equipment under test.

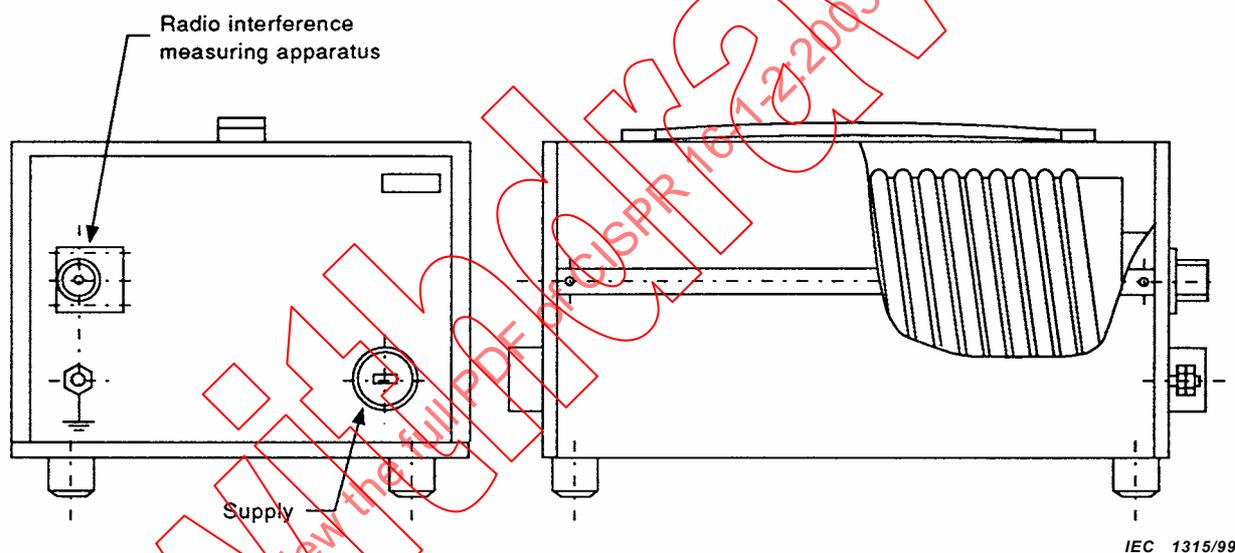


Figure A.4 – A general view of the artificial mains network

### A.7.3 Isolation of the inductor

Figure A.5 shows the attenuation to signals on the mains supply when the inductor is used in the circuit of figure 4 but without the isolation section L2, C2, and R2. The attenuation is determined as that between the supply mains terminal and the radio disturbance measuring apparatus terminal. In the case of curve 1, the internal impedance of the signal generator at the mains terminal is 50  $\Omega$  resistive. In curve 2, the internal impedance of the generator is varied in accordance with the nominal value of the magnitude of input impedance of the artificial mains network as given in figure A.5.

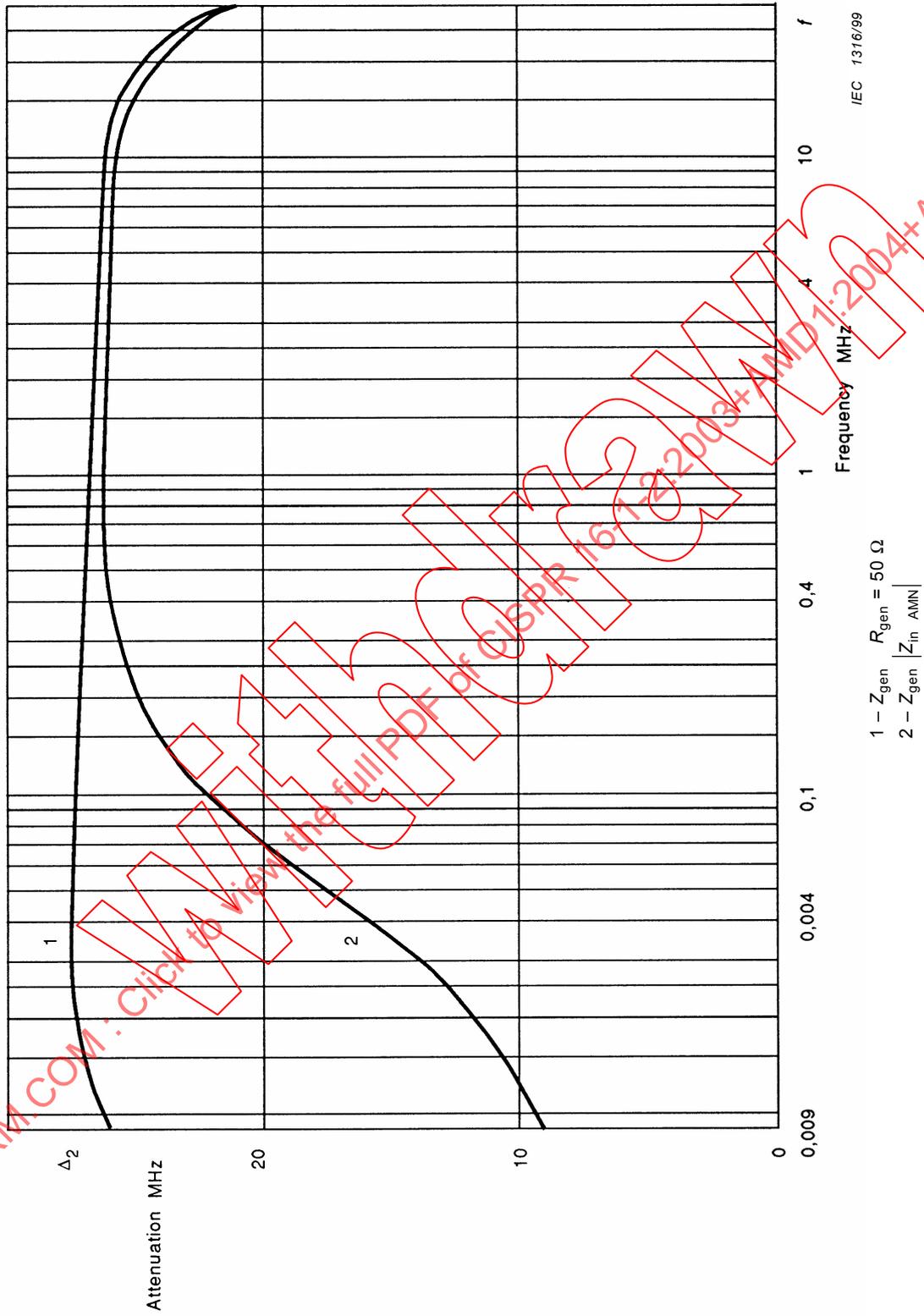


Figure A.5 – Attenuation of an artificial mains network filter

### A.8 Measurement of the voltage division factor of an artificial mains V-network

The voltage division factor may be determined using a test set-up as given by figures A.6a and A.6b for each test configuration of a V-network. It shall be measured on each line with each internal connection (e.g. with manual or remote switching configurations) using a network analyzer or using a signal generator and a measuring receiver or an RF-voltmeter with a high impedance (low capacitance) probe. All lines of the EUT port which are not connected to the RF port shall be terminated with 50 Ω.

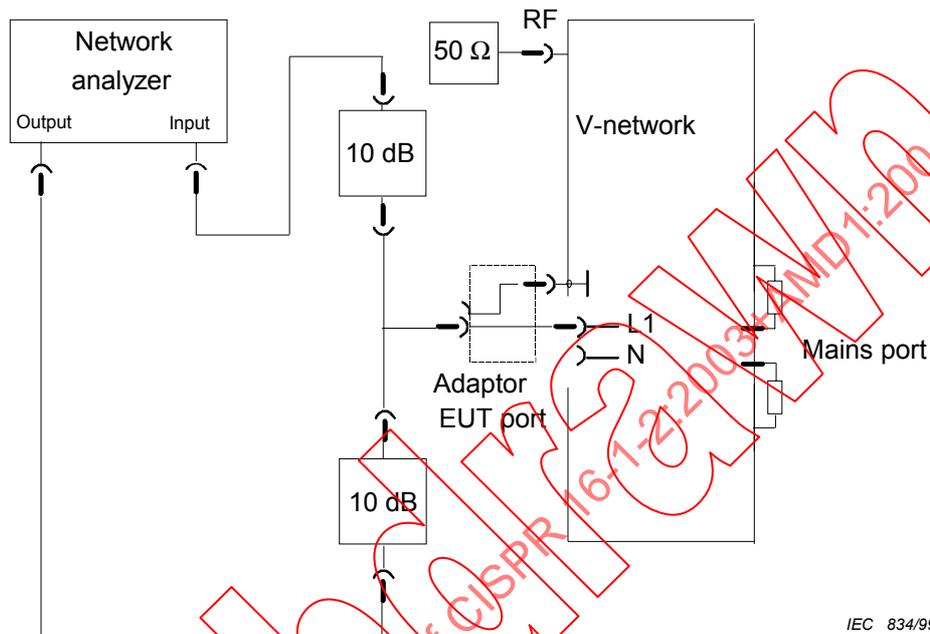


Figure A.6a – Test set-up for normalization of the network analyzer

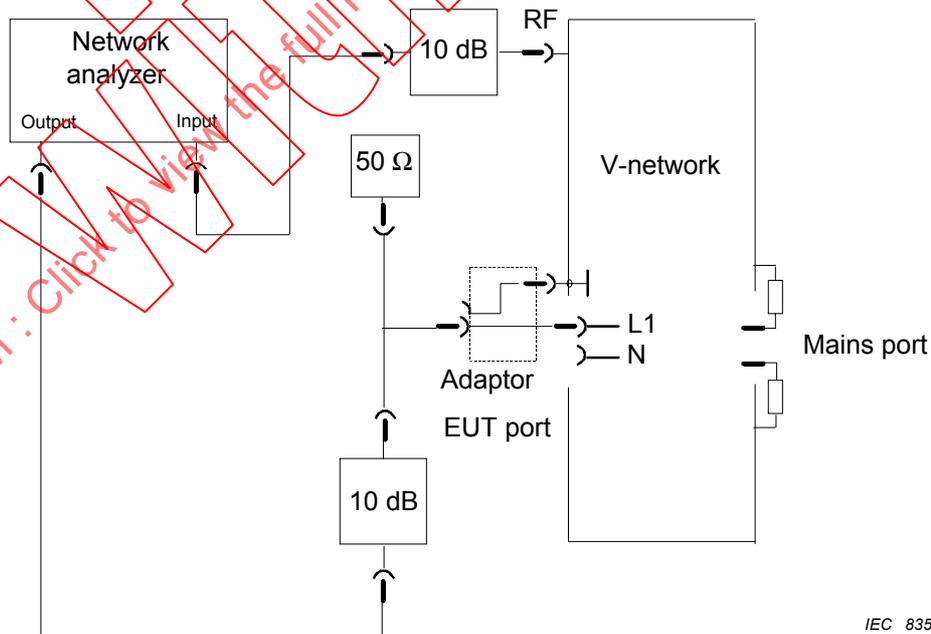


Figure A.6b – Test set-up for measurement of the voltage division factor using a network analyzer

Since the EUT port presents a frequency-dependant input impedance, the network analyzer needs to be normalized, using the measured voltage level at the EUT port.

If a signal generator and an RF-voltmeter with a high-impedance probe are used, the EUT port is fed via a 50  $\Omega$  pad and the RF port is terminated with a 50  $\Omega$  load while determining the voltage division factor by two subsequent measurements on the EUT and RF ports.

The construction of the adaptor used at the EUT port is critical for the calibration. The connections must provide low impedance and the T-connector must be placed as close as possible to the EUT port and earth terminals. The 10 dB pads are used to provide exact 50  $\Omega$  source and load impedances for accurate measurements.

Each line of the mains port shall be terminated with 50  $\Omega$  relative to the chassis.

For a 150  $\Omega$  V-network the voltage division between the EUT port and the measuring receiver port, i.e. 150  $\Omega$ /50  $\Omega$ , must be taken into consideration.

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## Annex B (informative)

### Construction, frequency range, and calibration of current probes (clause 5)

#### B.1 Physical and electrical considerations for current probes

The physical size of the current probe is a function of the maximum cable size to be measured, the maximum power current flowing in the cable, and the range of signal frequencies to be measured.

The current probe is usually of toroidal shape with the conductor to be measured placed within the centre opening of the toroid. Existing requirements and manufacturers' specifications show that the centre opening may vary from 2 mm to 30 cm in diameter. The secondary winding is placed on the toroid in such a manner as to facilitate the clamp-on function of the probe. The toroidal core and winding is enclosed with a shield to prevent electrostatic pick-up. The shield has a gap to prevent it from being a shorted turn on the transformer.

Typical current probes for disturbance measurements use seven to eight secondary turns. This number of turns is an optimized turns-ratio to ensure a maximized flat frequency range and an insertion impedance of 1  $\Omega$  or less. For frequencies below 100 kHz laminated silicon steel cores are used. Ferrite cores are used between 100 kHz to 400 MHz and air cores are used between 200 MHz to 1 000 MHz with a balanced coil to unbalanced 50  $\Omega$  output transformer. Figure B.1 shows the configuration of a typical current probe.

The current probe is generally used as a pick-up device for disturbance measurements. Therefore, it is designed to transfer the disturbance current to a voltage which can be detected by the meter. The sensitivity of the current probe may be expressed conveniently in terms of transfer impedance. Transfer impedance is defined as the ratio of secondary voltage (generally across a 50  $\Omega$  resistive load) to the primary current. The transfer admittance is sometimes used instead.

Overall sensitivity of the current probe and disturbance receiver is also a function of the receiver sensitivity. Minimum detectable disturbance current in a conductor is the ratio of receiver sensitivity (V) to current probe transfer impedance ( $\Omega$ ). For instance, if a one microvolt (1  $\mu$ V) receiver and a current probe with a transfer impedance of 10  $\Omega$  are used, then the minimum measurable disturbance current is 0,1  $\mu$ A. However, if a 10  $\mu$ V receiver and a current probe with a transfer impedance of 1  $\Omega$  are used, then the minimum measurable current is 10  $\mu$ A. To obtain maximum sensitivity, the transfer impedance should be as high as possible.

The transfer impedance  $Z_T$  is often expressed in terms of decibels (dB) above 1  $\Omega$ . This is a convenient unit in reference to the more general disturbance units of decibels above 1  $\mu$ V or 1  $\mu$ A ( $Z_T$  in terms of decibels above 1  $\Omega$  is taken as  $20 \log Z_T$ ).

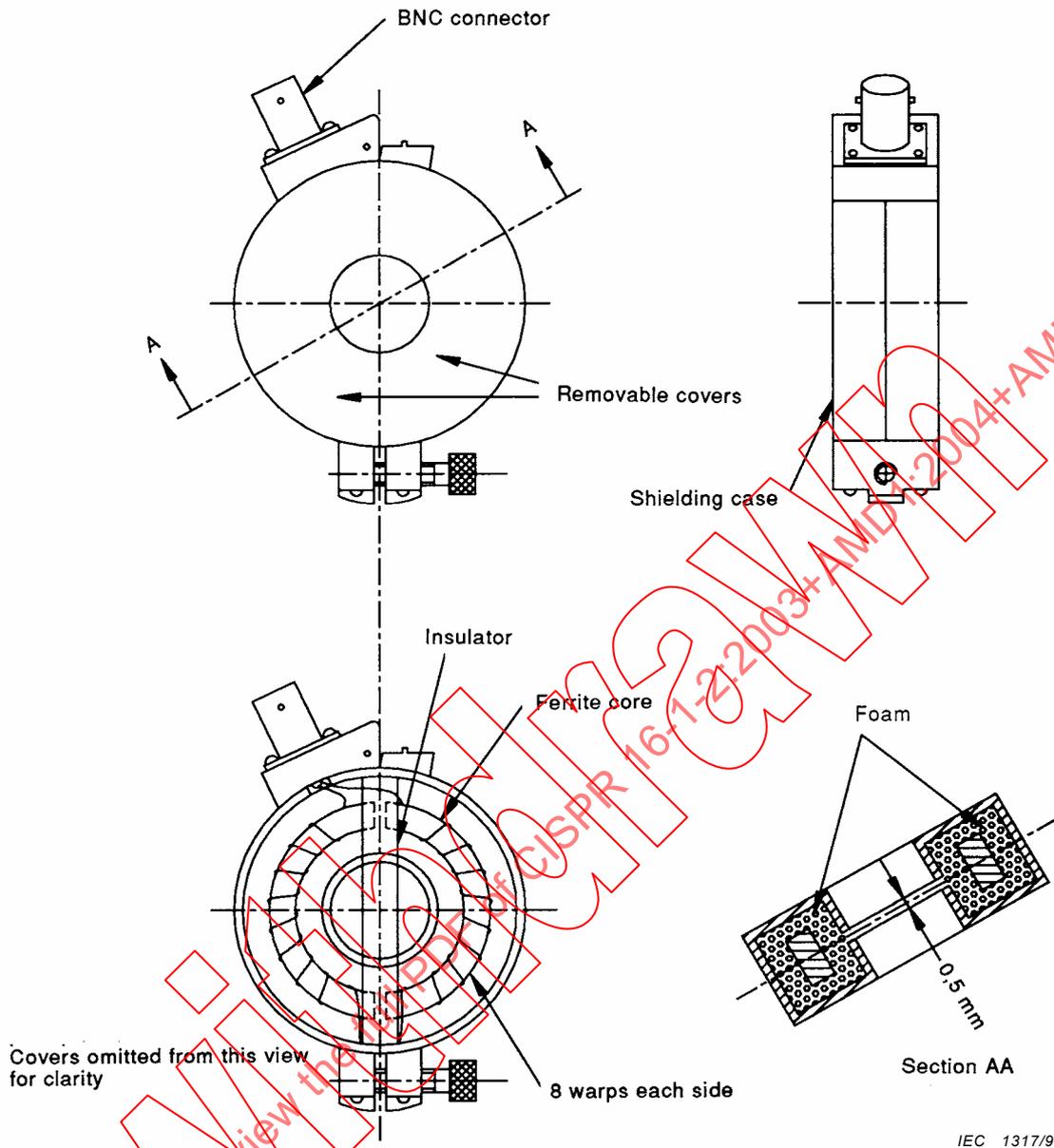


Figure B.1 – Typical current probe configuration

## B.2 Equivalent electrical circuit of current probe

The current probe may be represented by an exact equivalent circuit from general transformer theory. It is not necessary to repeat the circuit here since it is shown in many standard textbooks\*. After considerable simplification of the exact circuit and derived equations, the following equations for the transfer impedance result:

$$\text{High-frequency case: } Z_T = \frac{\omega M}{[(\omega L / R_L)^2 + (\omega^2 LC - 1)^2]^{1/2}}$$

$$\text{Mid-frequency case: } Z_T = MR_L / L \quad \text{when } (\omega^2 LC = 1)$$

$$\text{Low frequency case: } Z_T = \frac{\omega M}{[(\omega L / R_L)^2 + 1]^{1/2}}$$

where

$Z_T$  is the transfer impedance;

$M$  is the mutual inductance between primary and secondary windings;

$L$  is the inductance of secondary winding;

$R_L$  is the load impedance of secondary (usually 50  $\Omega$ );

$C$  is the distributed capacitance of secondary;

$\omega$  is the angular frequency in radian/second.

The following conclusions result from these equations:

- 1) The maximum transfer impedance at mid-frequency, for a constant load impedance, is directly proportional to the ratio of mutual inductance to secondary inductance ( $R_L$  being constant).
- 2) The high-frequency half-power point occurs when the reactance of the secondary distributed capacitance is equal to the load resistance.

## B.3 Deleterious effects of current probe measurements

The current probe is essentially a toroidal transformer and therefore reflects the secondary impedance into the primary. For an 8-turn secondary winding and a 50  $\Omega$  load, typically the insertion impedance is approximately 1  $\Omega$ . As long as the combination of source and load impedances of the circuit to be measured is greater than 1  $\Omega$  the application of the current probe will not greatly alter the primary current flow. However, if the sum of the circuit source and load impedances is less than the insertion impedance, the application of the current probe may alter the primary current considerably.

One intended current probe application is the measurement of disturbance current on primary power lines which may carry up to 300 A of d.c. or 100 A of a.c. The current probe may also be used in the vicinity of devices which generate strong external magnetic fields. The current probe transfer impedance shall not be altered by these power currents or flux densities. Therefore, the magnetic circuit shall be designed so that it will not saturate. Since the a.c. power currents may be in the frequency range of 20 Hz to 15 kHz, the current probe output at these power frequencies may damage the input circuit of the associated receiver. A possible solution is the insertion of power-frequency rejection filters between the current probe and the receiver. Figure B.2 shows a high-pass filter with 9 kHz cut-off frequency.

\* MIT Staff: *Magnetic Circuits and Transformers*, John Wiley & Sons, Inc., New York, N.Y., 1947.

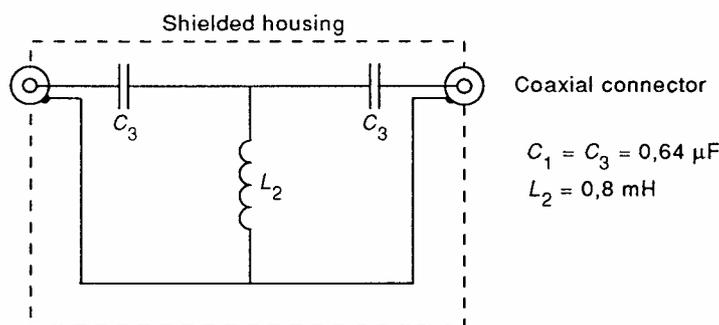


Figure B.2 – High-pass filter with cut-off frequency of 9 kHz

#### B.4 Typical frequency response characteristics of current probes

Figure B.3 shows the typical frequency response characteristics of current probes, with flat passbands of: a) 100 kHz to 100 MHz; b) 30 MHz to 300 MHz; and c) 200 MHz to 1 000 MHz.

#### B.5 A shielding structure for use with current probes

A current probe with the addition of a conductive (e.g., copper, brass, etc.) shielding structure may be used to measure either asymmetric (common mode) or symmetric (differential mode) disturbance current. The method is usable from 100 kHz to 20 MHz. The essential feature of this method is a modified RF current probe combined with a high-pass filter. The purpose of the high-pass filter is to enhance the rejection of the power frequency current in the output of the current probe. The test arrangement is described in CISPR 16-2-1.

##### B.5.1 Theoretical model

The set-up for current measurement using the artificial mains network is shown in figure B.4a. The components of the disturbance currents are:

- $I_1$  current in the live mains conductor
- $I_2$  current in the neutral mains conductor
- $I_C$  asymmetric current
- $I_D$  symmetric current

NOTE The phase angle between  $I_1$  and  $I_2$  is assumed zero. This is the case for leads of less than 1 m and frequencies below 30 MHz.

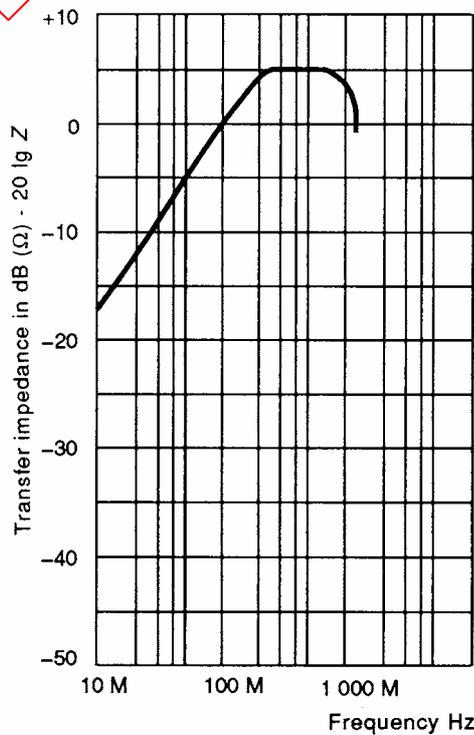
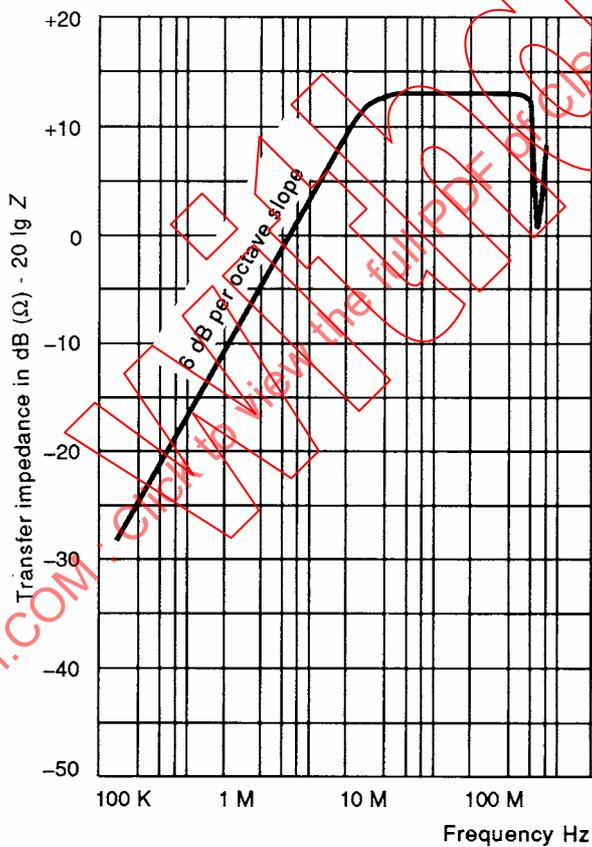
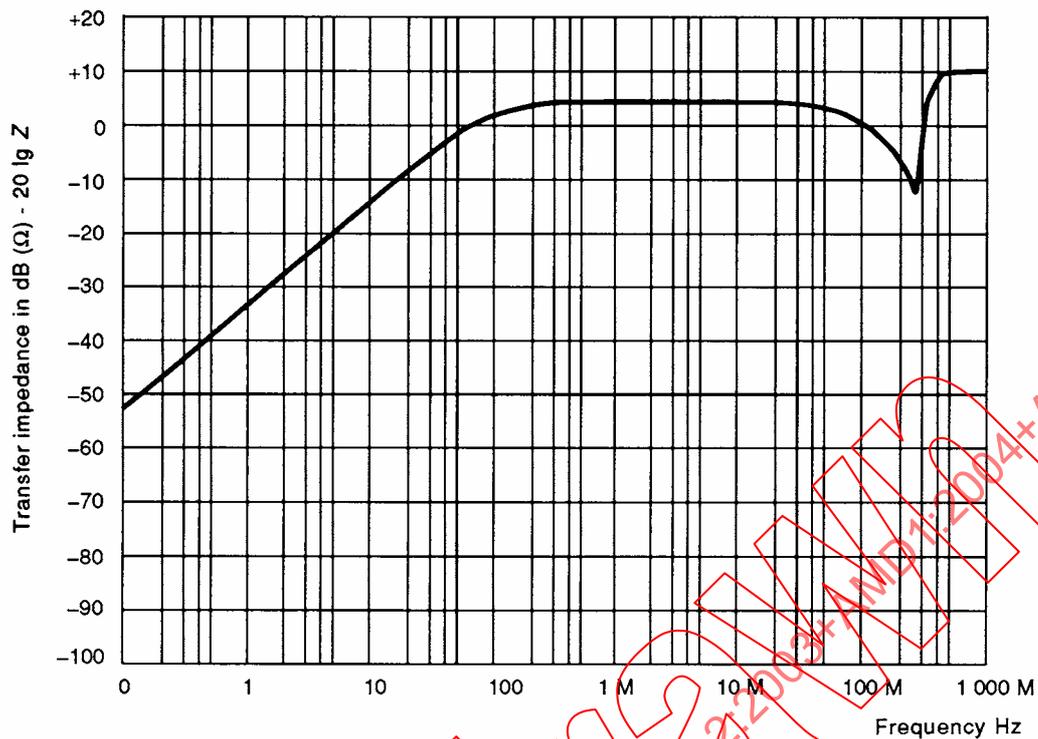
It can be seen from figures B.4a and B.4b that the currents have the following relations:

$$I_1 = I_C + I_D$$

$$I_2 = I_C - I_D$$

$$2 I_C = I_1 + I_2$$

$$I_D = I_1 - I_2$$



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Figure B.3 – Transfer impedance of typical current probes (see clause B.4)

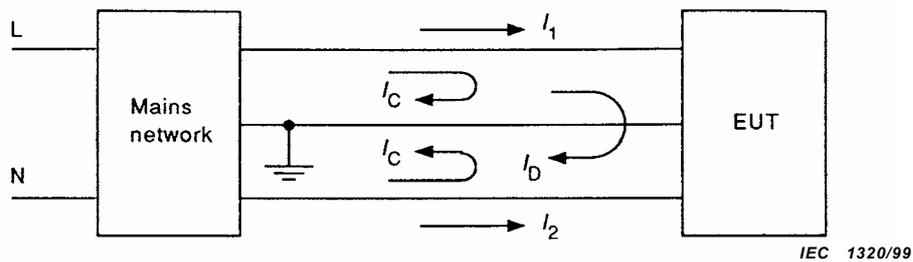


Figure B.4a – CISPR test circuit with interference currents

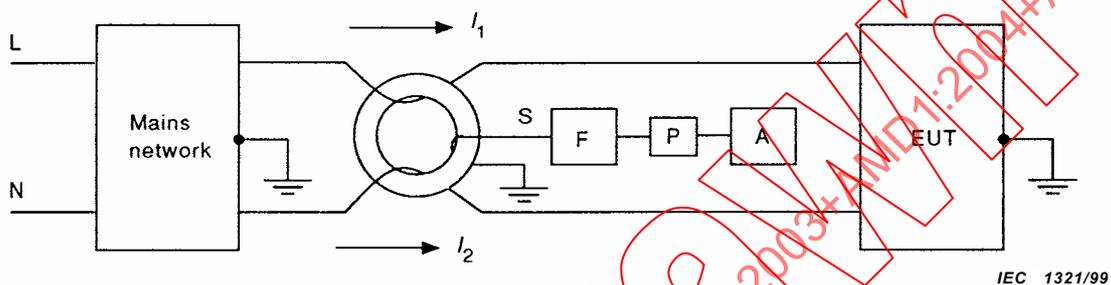


Figure B.4b – Test circuit which differentiates common (asymmetrical mode) and differential (symmetrical) mode noise

Thus a current probe clamped around the conductors so that  $I_1$  and  $I_2$  would add gives an output due solely to the asymmetrical current; whereas, subtraction of the currents would yield an output related only to the symmetrical current. A 6 dB correction of the measured value only for the asymmetrical current is required due to the factor of 2 in the equation for the asymmetrical current (see figure B.4b).

### B.5.2 Construction of the shielding structure

The additional shield required is shown in figure B.5. The dimensions shown are for a current probe with a centre core of 51 mm diameter. For other sizes of current probes the dimensions are scaled accordingly.

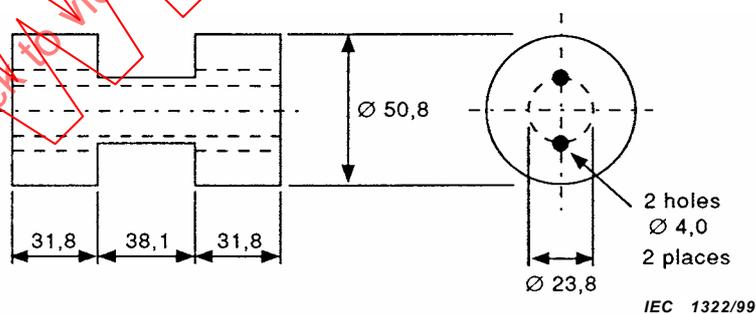


Figure B.5 – Shield configuration used with current transformer  
(The material should be highly conductive, e.g. copper or brass)

This structure serves to position the unshielded conductors in the current probe and to provide additional shielding from any external linkage when the output is grounded at one end. Insulated (0,75 mm<sup>2</sup>), stranded wire is passed through the hole and fitted at each end with terminals to accept the shielded leads from the mains network and to the equipment under test. The diameter of the centre of the shield is the built-up with insulating tape so that the wires are firmly held in the slots and so that this portion of the assembly fits snugly in the current probe when it is closed.

The shield is positioned in the current probe such that the plane of the leads is perpendicular to the plane of the gaps in the core halves of the probe. It is important to ensure that the shielding structure as shown in figure B.5 is insulated from the current probe housing so that the gap in the housing is not shorted.

### B.5.3 High-pass filter

A high-pass filter, if needed, is inserted between the output of the current probe and the measuring receiver. This filter may be part of the measuring receiver. (See figures B.2 and B.4b).

### B.6 Calibration of current probes

Calibration of current probes may be done by a jig which is made of two halves of a coaxial adapter. When assembled with the current probe in place, it forms a coaxial line the outer conductor of which encloses the current probe and the inner conductor passes through the probe aperture (see figure B.8).

The equivalent calibration circuit is shown in figure B.6. When the coaxial line is well matched the current  $I_P$  through the inner conductor may be calculated from a measurement of the voltage  $V_1$  on the line. The body, if metal, or shield of the probe should be taken into account in the design of the jig to achieve a good coaxial line. If the voltage output of the current probe is  $V_2$  the transfer admittance may be calculated using the following formula:

$$k = V_1 - V_2 - 34$$

where

$k$  is the transfer admittance in dB(S);

$V_1$  is the RF voltage on the coaxial line in dB( $\mu$ V);

$V_2$  is the RF output voltage of the probe in dB( $\mu$ V);

the factor 34 is related to the 50  $\Omega$  load impedance.

The transfer admittance  $k$  is used to calculate the value of the measured current  $I_P$  by the formula:

$$I_P = V_2 + k$$

where

$I_P$  is in dB( $\mu$ A), and

$V_2$  is in dB( $\mu$ V)

$k$  is in dB(s)

Figure B.7 shows a typical calibration result, figure B.8a shows the return loss and figure B.8b shows picture of the coaxial adapter jig.

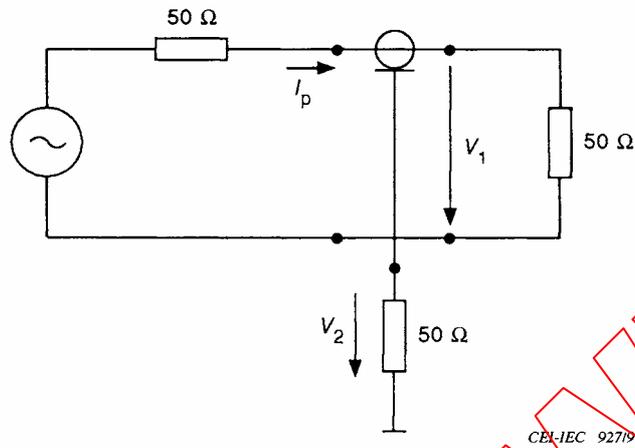


Figure B.6 – Schematic diagram of circuit with coaxial adapter and current probe  
Current probe factor  $k$  measurement

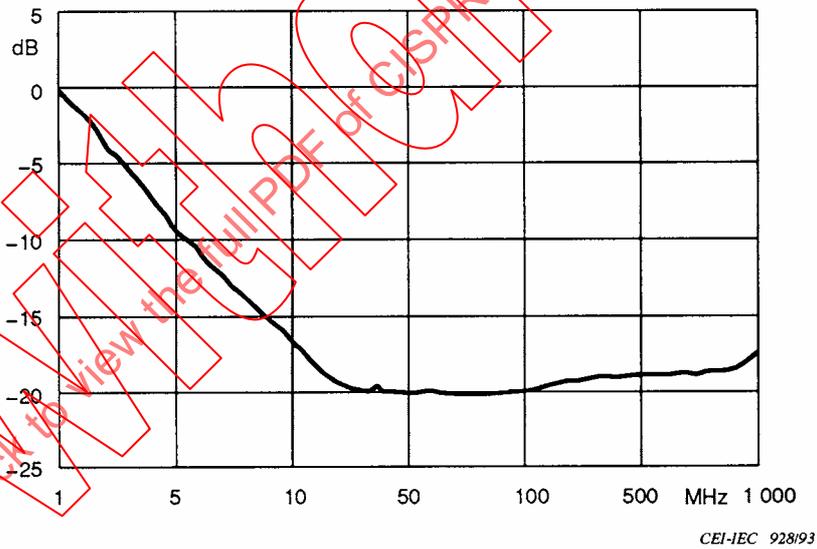


Figure B.7 – Current probe factor  $k$  as a function of frequency

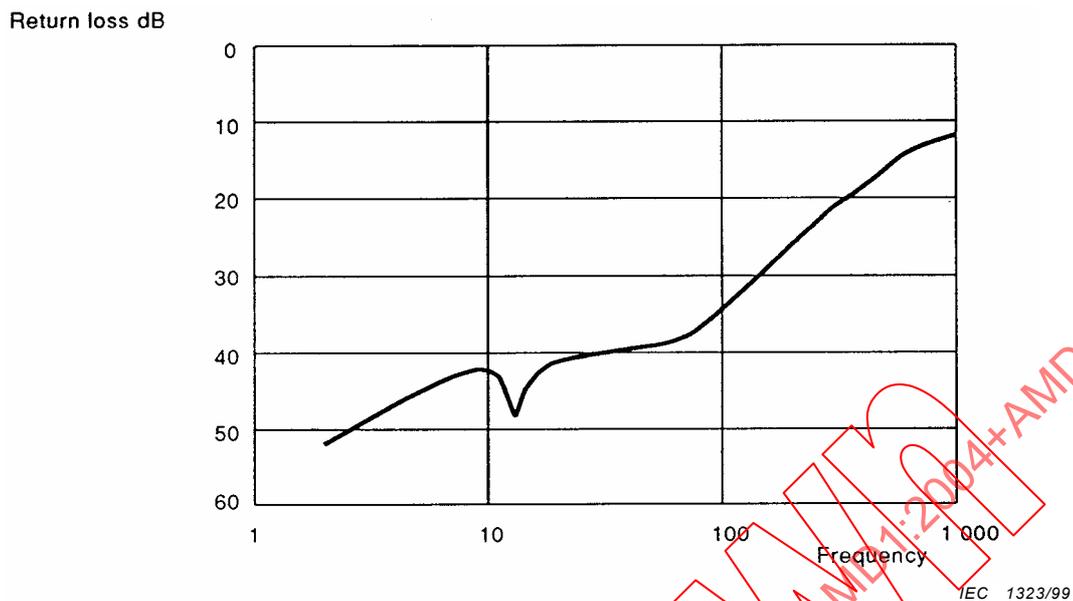
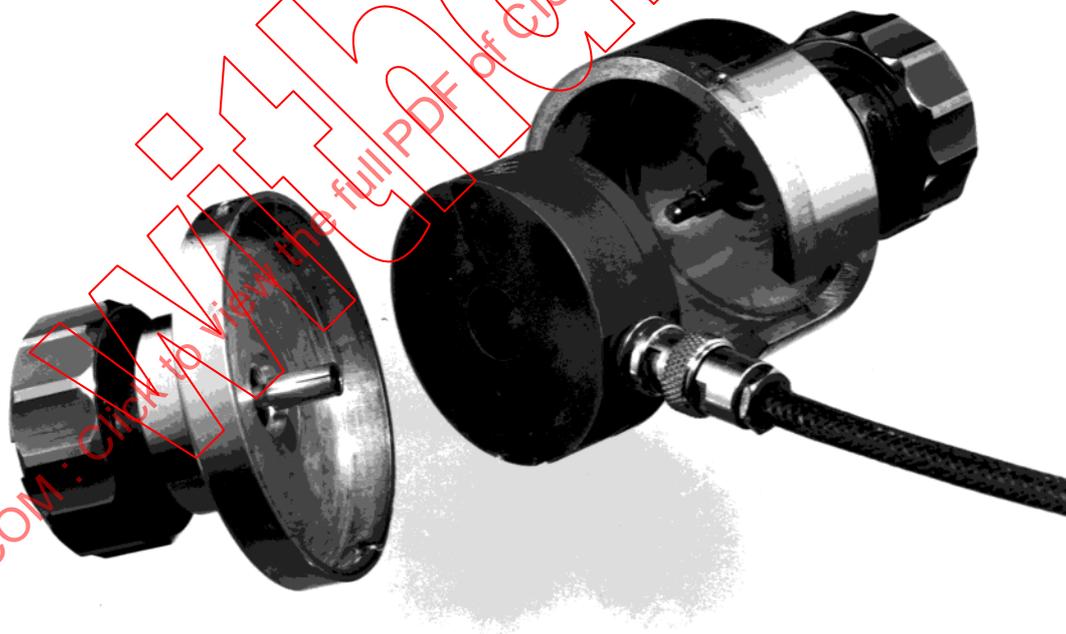


Figure B.8a – Return loss

Return loss of the coaxial adapter (see below) terminated with 50  $\Omega$  and with the current probe inside. The current probe is also terminated with 50  $\Omega$ .



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Figure B.8b – Current probe between the two halves of the coaxial adapter

## Annex C (informative)

### Construction of the coupling units for current injection for the frequency range 0,15 MHz to 30 MHz (clause 6)

#### C.1 Coupling unit type A for coaxial antenna input

The circuit diagram and construction are similar to the type A unit shown in figure C.1, except that the inductance value is 280  $\mu\text{H}$ .

Construction of the 280  $\mu\text{H}$  inductor:

Core: two ferrite rings, material 4C6 or equivalent, placed together, dimensions 36 mm outer diameter, 23 mm inner diameter, 30 mm thick.

Winding: 28 turns of a fully screened miniature coaxial cable, e.g. UT-34, wire diameter 0,9 mm, with an outer insulation plastic tubing of 1,5 mm outer diameter.

#### C.2 Coupling unit type M, for mains leads

The circuit diagram and construction are similar to the type M unit shown in figure C.2, except that the two inductors are 560  $\mu\text{H}$  each, and  $C1 = 0,1 \mu\text{F}$  and  $C2 = 0,47 \mu\text{F}$ .

Construction of the 560  $\mu\text{H}$  inductor:

Core: two ferrite rings, material 4C6 or equivalent, placed together, dimensions 36 mm outer diameter, 23 mm inner diameter, 30 mm thick.

Winding: 40 turns of insulated copper wire, 1,5 mm outer diameter.

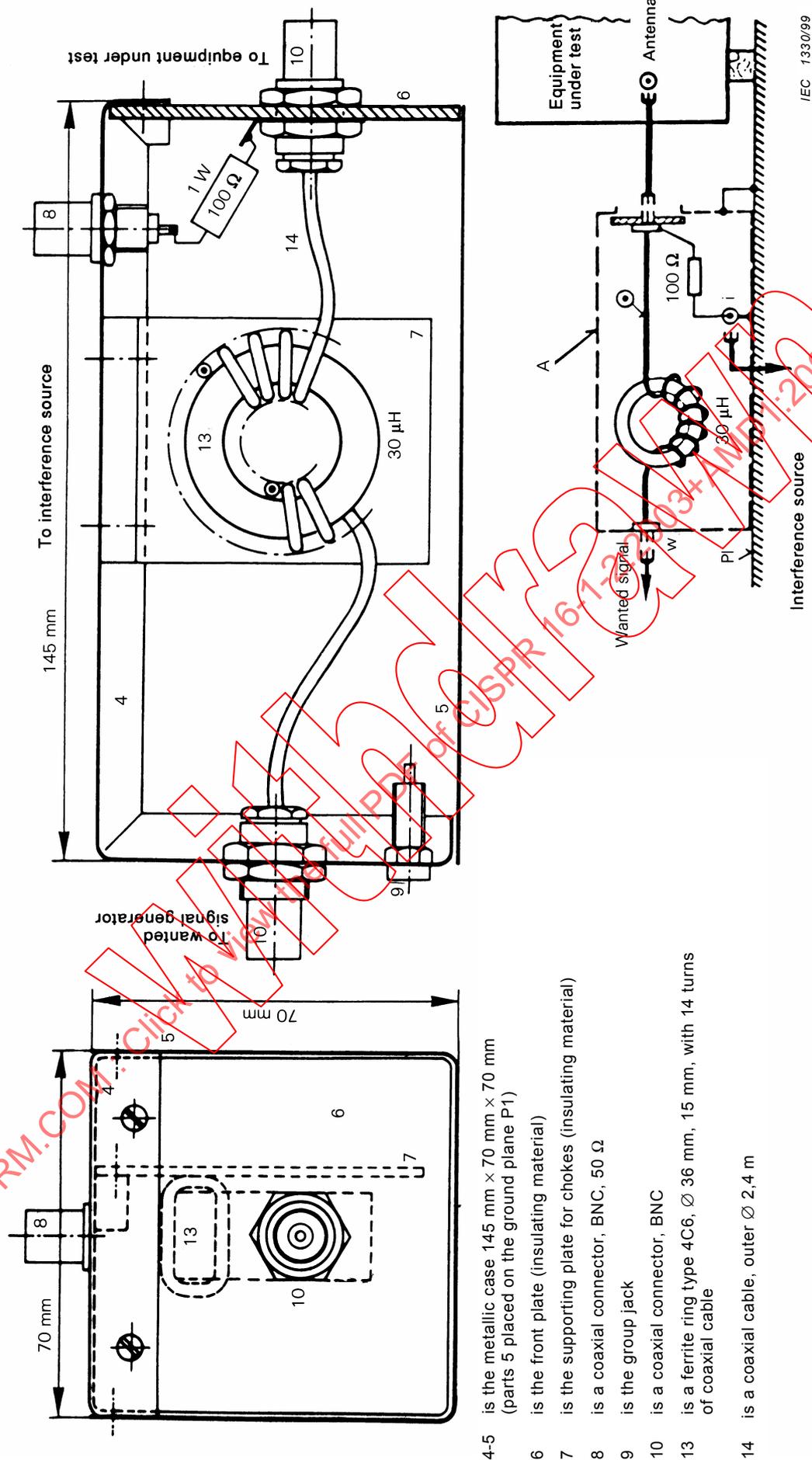
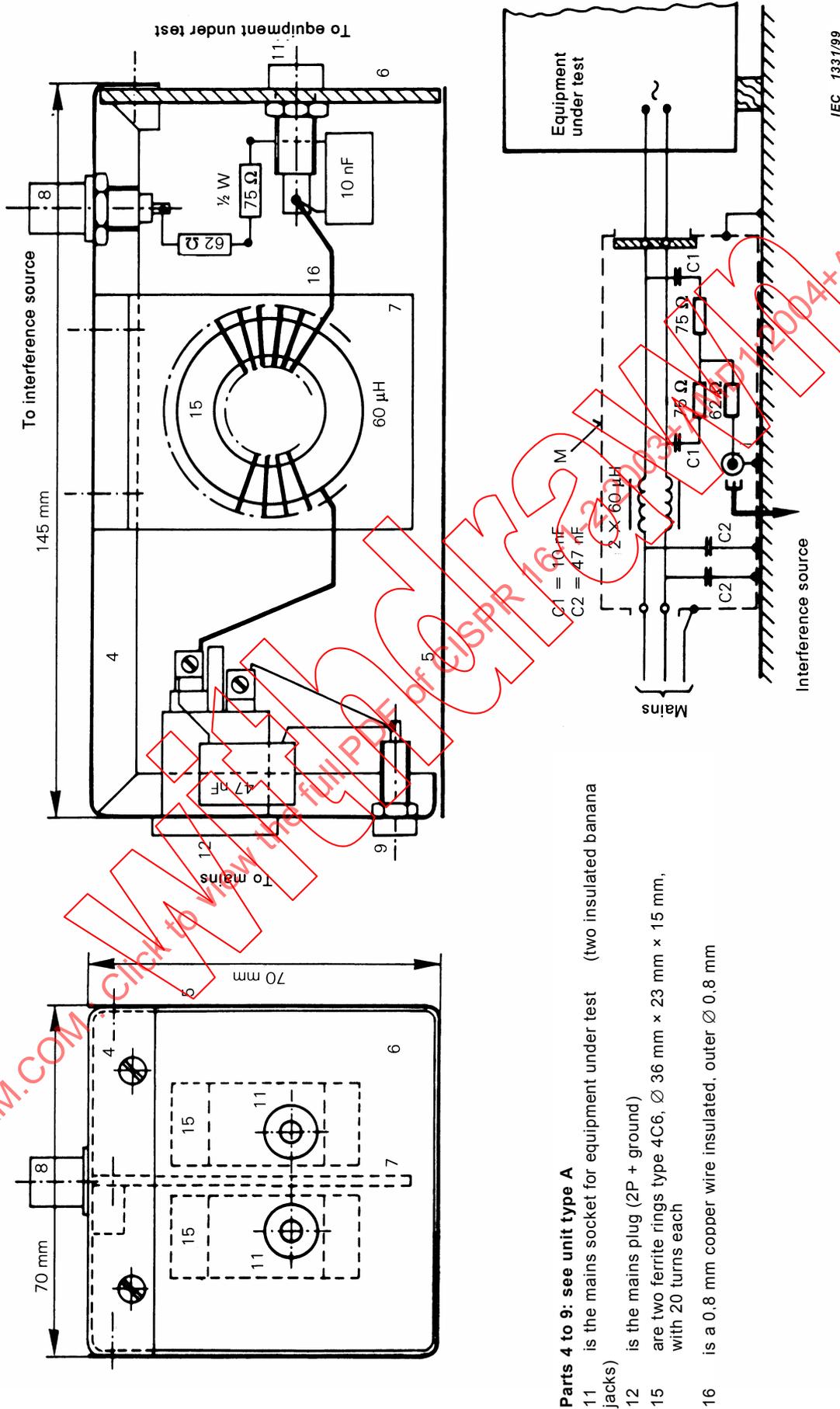


Figure C.1 – Example of coupling unit A, for coaxial input  
Schematic diagram and construction details (see clause C.1 and clause D.2)

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- 4-5 is the metallic case 145 mm x 70 mm x 70 mm (parts 5 placed on the ground plane P1)
- 6 is the front plate (insulating material)
- 7 is the supporting plate for chokes (insulating material)
- 8 is a coaxial connector, BNC, 50 Ω
- 9 is the group jack
- 10 is a coaxial connector, BNC
- 13 is a ferrite ring type 4C6, Ø 36 mm, 15 mm, with 14 turns of coaxial cable
- 14 is a coaxial cable, outer Ø 2,4 mm



IEC 1337/99

**Parts 4 to 9: see unit type A**

- 11 is the mains socket for equipment under test (two insulated banana jacks)
- 12 is the mains plug (2P + ground)
- 15 are two ferrite rings type 4C6,  $\varnothing$  36 mm x 23 mm x 15 mm, with 20 turns each
- 16 is a 0.8 mm copper wire insulated, outer  $\varnothing$  0.8 mm

**Figure C.2 – Example of coupling unit type M, for mains leads. Schematic diagram and construction details (see clause C.2 and clause D.2)**

### C.3 Coupling unit type L, for loudspeaker leads

The circuit diagram and construction are similar to the type L unit shown in figure C.3 with two separate inductors of 560  $\mu\text{H}$  each and  $C1 = 47 \text{ nF}$  and  $C2 = 0,22 \mu\text{F}$ .

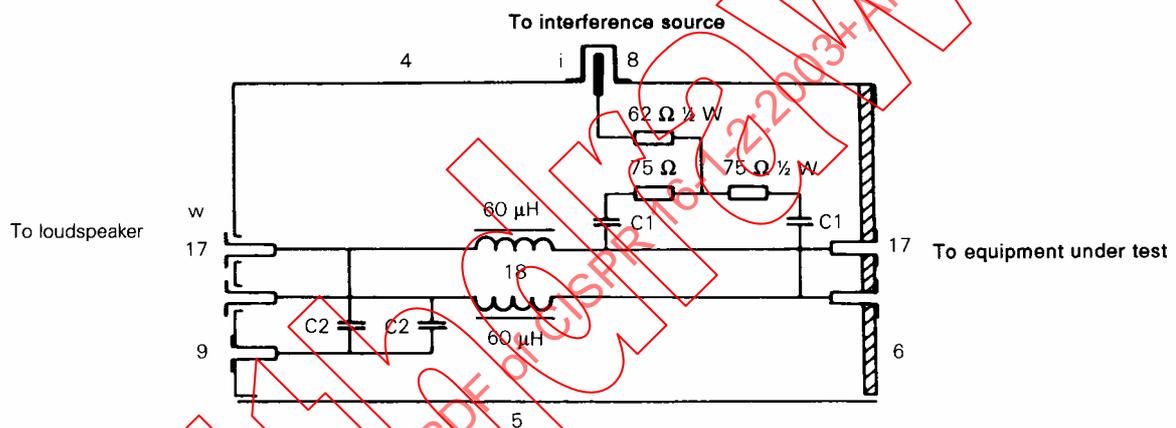
Construction of each 560  $\mu\text{H}$  choke:

Core: one ferrite ring, material 4C6 or equivalent, dimensions 36 mm outer diameter, 23 mm inner diameter, 15 mm thick.

Winding: 56 turns of varnish insulated copper wires, 0,4 mm diameter.

NOTE Characteristics of magnetic ferrite type 4C6:

Relative initial permeability  $\mu_i = 120$   
Loss factor  $\tan\delta/\mu_i < 40$  at 2 MHz,  $< 100$  at 10 MHz  
Resistivity  $\rho = 10 \text{ k}\Omega\text{m}$



Parts 4-5-6-8-9: see unit type A.

17 are insulated banana jacks

18 are two inductances 60  $\mu\text{H}$  each.

For each inductance:

Core: one ferrite ring, type 4C6,  
 $\varnothing 36 \text{ mm} \times \varnothing 23 \text{ mm} \times 15 \text{ mm}$

Winding: 20 turns copper wire insulated  
outer  $\varnothing 1,2 \text{ mm}$

Mounting of the inductances: see unit type M

$C1 = 10 \text{ nF}$

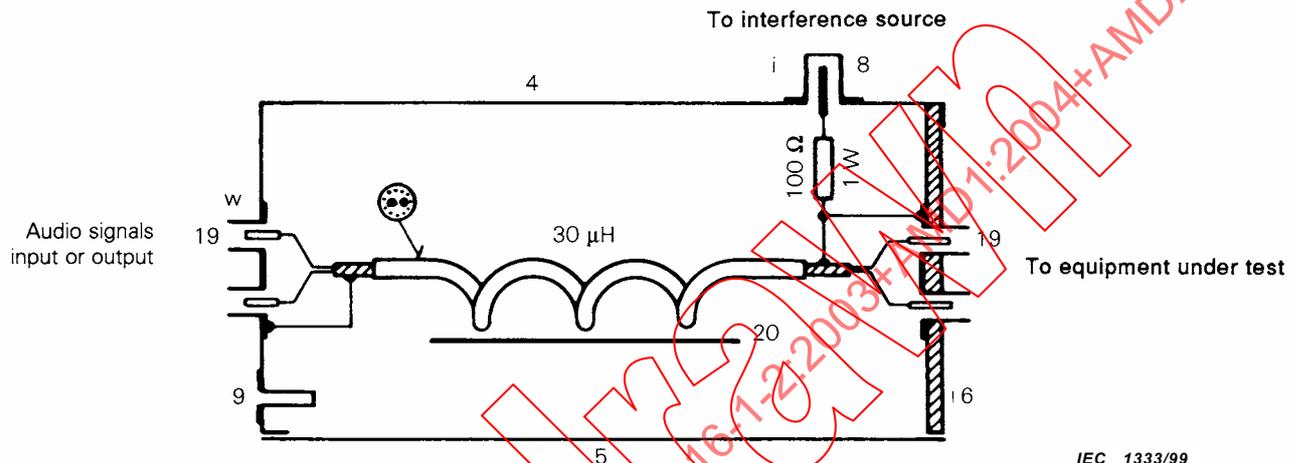
$C2 = 47 \text{ nF}$

Figure C.3 – Example of coupling unit type L for loudspeaker leads  
Schematic diagram and simplified construction drawing  
(see D.2)

#### C.4 Coupling unit type Sw, for audio-frequency signals

The circuit diagram and construction are similar to the type Sw unit shown in figure C.4, except with the 280  $\mu\text{H}$  inductor described in clause C.1. The screened cable may be an audio-frequency type, and its diameter shall be not larger than 2,1 mm.

NOTE The type A coupling unit described in C.1 may be used for this purpose, if the two stereo signal cables of the equipment under test are connected together.



IEC 1333/99

Parts 4-5-6-8-9: see unit type A.

19 are Cinch or DIN sockets

20 is the inductance 30  $\mu\text{H}$ .

Core: one ferrite ring, type 4C6,  
 $\varnothing 36 \text{ mm} \times \varnothing 23 \text{ mm} \times 15 \text{ mm}$

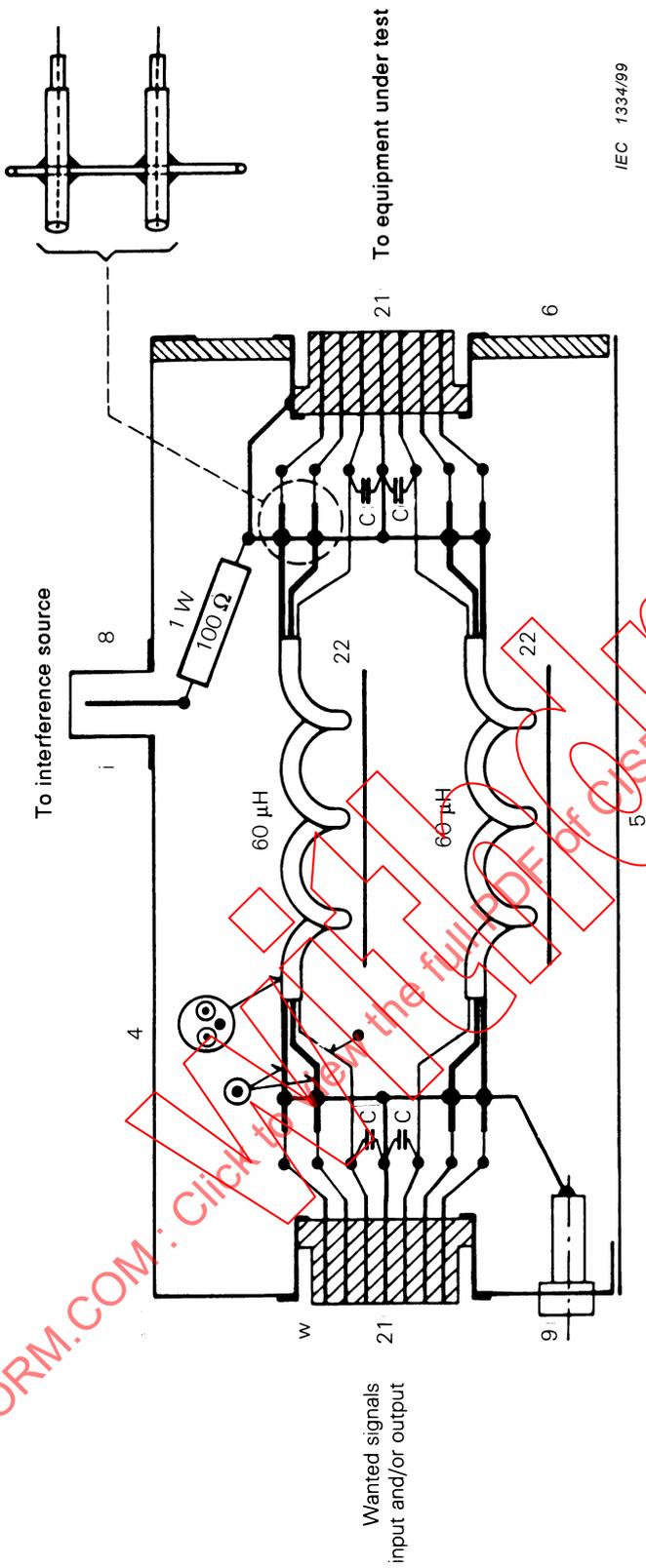
Winding: 14 turns with a screened twisted pair:  
outer diameter of cable insulation 2,8 mm

Mounting of the inductance: see unit type A

**Figure C.4 – Example of coupling unit type Sw, for audio signals.  
Schematic diagram and simplified construction drawing  
(see D.2)**

#### C.5 Coupling unit type Sw, for audio, video, and control signals

The circuit diagram and construction are similar to the type Sw unit shown in figure C.5, except with two 560  $\mu\text{H}$  inductors constructed as described in clause C.2. The cable with three conductors shall have an outer diameter not larger than 1,5 mm. This may be achieved using two micro-coaxial cables type UT-20 (0,6 mm diameter) and a varnish insulated copper wire of 0,3 mm diameter.



IEC 1334/99

Parts 4-5-6-8-9: see unit type A

21 are multiple pins connector (e.g. 7 pins DIN-socket)

22 are two inductances 60 μH each. For each inductance:

Core: one ferrite ring, type 4C6,

∅ 36 mm x ∅ 23 mm x 15 mm

Winding: 20 turns with a three-lead cable

Cable: Two micro-coaxial cables, UT-34,

outer ∅ 0,9 mm + one copper wire

∅ 0,4 mm, varnish insulated

outer insulation: tube outer ∅ 2,4 mm

Mounting of the inductances: see unit type M

C = 1 nF (or more, if it is acceptable by the signal source)

Figure C.5 – Example of coupling unit type Sw, for audio, video and control signals  
Schematic diagram and simplified construction drawing (see D.2)

## Annex D (informative)

### Principle of operation and examples of coupling units for conducted current immunity measurements (clause 6)

#### D.1 Principle of operation

The principle of operation is illustrated in figure D.1. The inductance  $L$  presents a high impedance to the injected disturbance current. The filter  $L/C_2$  isolates the test apparatus (wanted signal generator or auxiliary equipment);  $C_1$  and  $C_2$  may be replaced by a short circuit if the a.c./d.c. conditions permit. The disturbance signal delivered from a generator with  $50\ \Omega$  internal resistance is injected via a  $100\ \Omega$  resistor  $R_1$  and a blocking capacitor  $C_1$  (if required) on to the leads or on to the shield of a coaxial cable.

#### D.2 Types of unit and their construction

The following types of coupling units are used:

- Type A: The RF coaxial units are to be used for coaxial leads carrying wanted signals in the RF frequency range. The construction details are shown in figure C.1. The  $100\ \Omega$  resistor (to make up the  $150\ \Omega$  source impedance from a  $50\ \Omega$  interference signal source) is bonded to the shield of the coaxial output connector in the unit.
- Type M: These are for use with mains leads. The construction details are shown in figure C.2. The injection of the disturbance current is done asymmetrically on both wires through an equivalent resistance of  $100\ \Omega$ . This unit is like an artificial mains delta network and presents, as seen from the equipment under test terminals, a symmetrical and asymmetrical equivalent resistive impedance of  $150\ \Omega$ .
- Type L: These are for use with loudspeaker leads. The construction details are shown in figure C.3. The impedance of the disturbance source is arranged as for Type M units.
- Type Sr and Sw: These are designed for use with audio, video and other auxiliary leads. They are multi-pin units which have to be adapted to a variety of pin numbers and connector configurations, as follows:
- Type Sw: These units provide a through path for audio, video, control or other signals, in which case filtering is required to ensure that the disturbance signal is directed towards the equipment under test. The construction details shown in figure C.4, indicate the simple filtering provided for audio signals with a screened pair wound on a toroid. In the case of multi-lead cables it may be necessary, for construction reasons, to separate the cable leads before winding upon a toroid shown in figure C.5. In both cases the disturbance current is injected via a  $100\ \Omega$  resistor on to the screen and the earth pins of the output connector, the screens of the shielded leads, and through capacitor on to the other (unshielded) leads.

Type Sr: These are designed for the case where there is no requirement to provide a through signal path. All leads of the cable are terminated with a matched load resistance. The construction details are shown in figure D.2. The disturbance current is injected via a 100  $\Omega$  resistor on to the screen (earthing) and the earth pins of the connector, to which point all the load resistors ( $R_1$  to  $R_n$ ) are connected also. It should be noted that a coupling unit of the type indicated in figures C.4 or C.5 terminated with a correct load impedance could be used for this purpose.

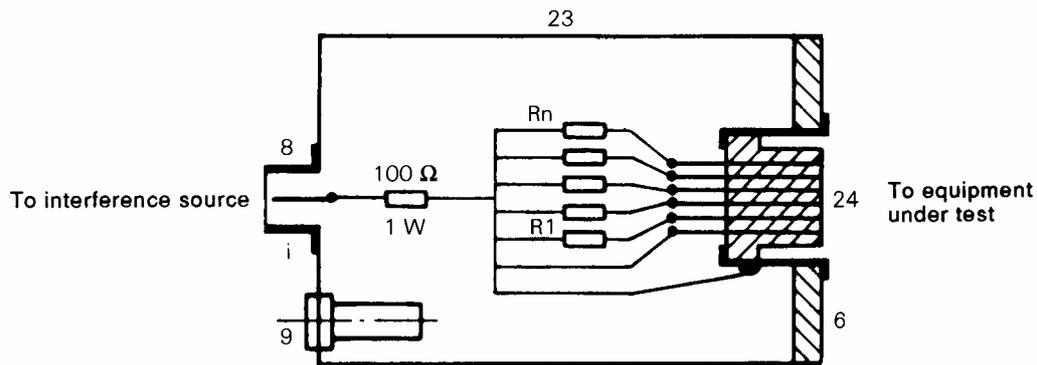
If the source impedance of the disturbance generator is not 50  $\Omega$ , the value of the series resistor is adjusted accordingly to make up the required 150  $\Omega$  impedance.

The RF choke coils shown in figures C.1 to D.2 have inductance values 30  $\mu\text{H}$  or 2 x 60  $\mu\text{H}$  in parallel and are satisfactory for the frequency range 1,5 MHz to 150 MHz. For the frequency range 0,15 MHz to 30 MHz, the inductance values are 280  $\mu\text{H}$  or 2 x 560  $\mu\text{H}$  in parallel respectively. Annex C describes their construction.

Precautions have to be taken in the layout in order to keep parasitic capacitance to the output terminals of the units as low as possible. It should be noted that the metal cases of the units are to be carefully connected to the ground plane using large section copper braid and unpainted cases.

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6-8-9: see unit type A

23 is the metallic case 100 mm × 55 mm × 55 mm

24 is the multiple-pin conductor or DIN-socket

R1 to Rn are the matched load resistances.

Examples: Coupling units Sr for audio equipment:

Phonograph	$\left\{ \begin{array}{l} \text{magnetic:} \\ 2 \times 2,2 \text{ k}\Omega \\ \text{crystal:} \\ 2 \times 470 \text{ k}\Omega \end{array} \right.$
Microphone:	2 × 600 Ω
Tuner:	2 × 47 kΩ
Tape recorder:	4 × 47 kΩ
Audio in/out:	4 × 47 kΩ

**Figure D.2 – Coupling unit type Sr with load resistances – Schematic diagram and simplified construction drawing (see clause D.2)**

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## Annex E (normative)

### Example and measurement of the parameters of the asymmetric artificial network (AAN)

#### E.1 Description of an example of an AAN: the T-network

Figure E.1 gives an example of an AAN, the T-network, having terminals  $a_1$  and  $b_1$  for connection to a conductor pair in a signal port of an EUT and RG for connection to the reference ground and, if applicable, to the safety earth or other ground connector of the EUT.

The symmetric signal which may be needed to have the EUT operating correctly is connected to the terminals  $a_2$  and  $b_2$ . The double choke  $L_1$  allows separate measurement of the asymmetric component of the disturbance. The two windings are designed such that the symmetric currents are suppressed by a high impedance whereas the impedance for asymmetric currents (passing to  $R_M$ ) shall be negligible.

The termination impedance of the network for the asymmetric disturbance voltage of  $150 \Omega$  is determined by the two resistors  $R_T$  ( $200 \Omega$ ), in parallel for the asymmetric current, in series with the resistor  $R_M$  ( $50 \Omega$ ). The resistor  $R_M$  is usually the input impedance of a measuring receiver. In this case the meter reading is typically 9.5 dB lower than the actual asymmetric value at the terminal of the EUT. The capacitor  $C_T$  is blocking d.c. currents thus allowing for d.c. supply voltages on the network leads without damaging the resistors and without affecting the properties of  $L_1$ , due to saturation.

Normally an AAN is inserted between an EUT and its associated equipment.

#### E.2 Measurements of the parameters of an asymmetric artificial network (AAN)

For the determination of compliance with the requirements of 7.1, the procedures for the measurement of the specified parameters described below are used.

##### a) Termination impedance

This impedance between the terminals  $a_1$  and  $b_1$  connected together, and terminal RG shall be checked with terminals  $a_2$  and  $b_2$  being alternatively open and short-circuited to the earth terminal RG (see Figure E.2).

##### b) Longitudinal conversion loss (LCL)

This rejection of the Y-network shall be measured in accordance with Figure E.3c. The network analyzer (NWA), applies its output signal to an LCL probe, which must have a residual longitudinal conversion loss (LCL) at least 10 dB higher than the required LCL of the AAN. For LCL probe verification, see Figure E.3a and for calibration, see Figure E.3b.

##### c) Decoupling attenuation

The decoupling attenuation shall be measured in accordance with Figure E.4.

##### d) Insertion loss of the symmetric circuit

The insertion loss of the symmetric circuit shall be measured in accordance with Figure E.5.

Two LCL probes can be used as baluns for the insertion loss test of the Y-network. Two identical baluns may be connected in series for the determination of their own insertion loss. Baluns can be designed such that the combined insertion loss of 2 baluns is less than 1 dB in the frequency range from 0,15 MHz to 30 MHz.

e) **Voltage division factor of the asymmetric circuit (calibration of the Y-network)**

The voltage division factor of the asymmetric circuit shall be measured in accordance with Figure E.6.

f) **Symmetric load impedance and transmission bandwidth**

This parameter is defined by the system. Y-networks may be optimized for a certain impedance with respect to transmission bandwidth. The transmission bandwidth may be measured for a certain symmetric load impedance using the test set-up of Figure E.5.

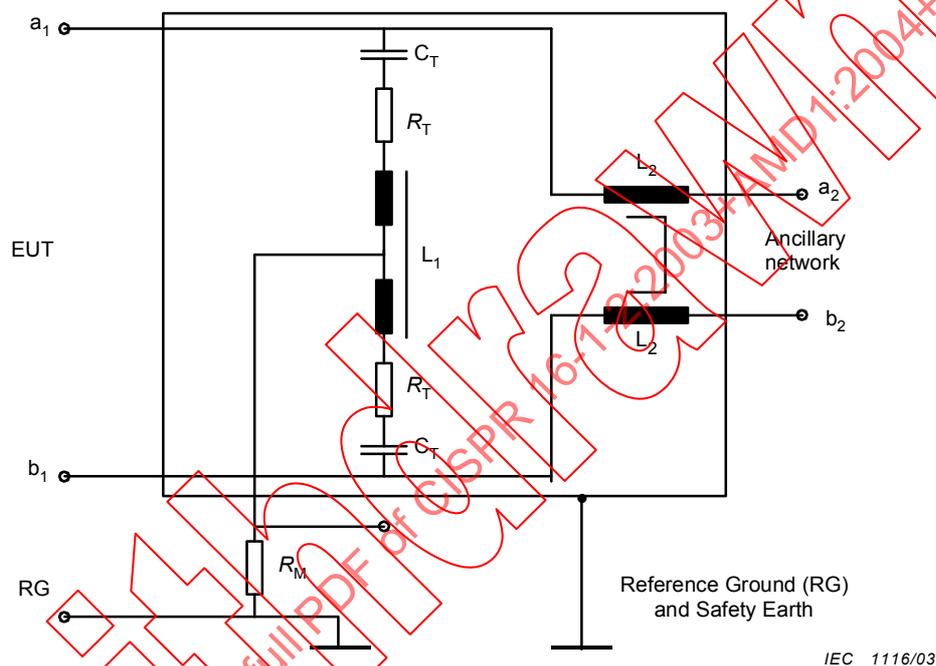
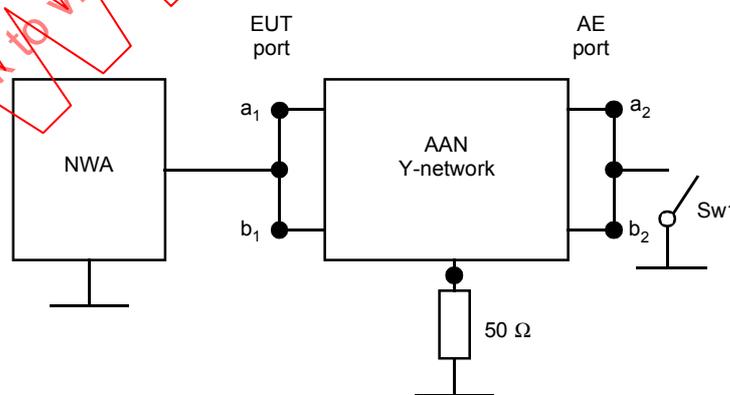


Figure E.1 – Example of a T-network circuit for one pair of wires



NOTE If the AAN is of higher order (i.e. more than 1 pair of wires), then all wires of the EUT port, respectively all wires of the AE port, are connected together.

Figure E.2 – Arrangement for the termination impedance measurement